Center for Space Microelectronics Technology

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Abstract

The 1988-1989 Technical Report of the Jet Propulsion Laboratory Center for Space Microelectronics Technology summarizes the technical accomplishments, publications, presentations, and patents of the center during the past two years. The report lists 321 publications, 282 presentations, and 140 new technology reports and patents.
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Director's Report

The Center for Space Microelectronics Technology (CSMT) was established in 1987 at the Jet Propulsion Laboratory (JPL) of the California Institute of Technology (Caltech). The CSMT's mission is to perform research and advanced development in the area of microelectronics to support new space missions for the National Aeronautics and Space Administration (NASA) and the U.S. Department of Defense (DoD).

The CSMT is chartered to investigate and advance innovative scientific concepts and phenomena, leading to the development of electronic materials and devices that will enable and enhance NASA and DoD space missions. The Center develops and evaluates new electronic and optical concepts for sensors, information processing, data storage, and real-time signal processing. It explores novel concepts in solid state devices for application in space. The Center also develops the technological base required to advance space computing concepts and architectures - in response to the unique requirements of the space environment.

The CSMT Board of Governors provides policy guidance and program oversight for the Center. The Chairman of the Board is the Director of JPL. The Board includes representatives of NASA, the Caltech Campus, and sponsoring agencies who maintain a significant relationship with the CSMT. The CSMT Board of Governors members are:

- Dr. Lew Allen (Chairman), Director, JPL.
- Mr. Arnold D. Aldrich, Associate Administrator, Office of Aeronautics and Space Technology, NASA.
- Dr. Craig I. Fields, Director, Defense Advanced Research Projects Agency (DARPA).
- Dr. Dwight Duston, Director, Innovative Science and Technology Office, Strategic Defense Initiative Organization.
- Dr. Thomas E. Everhart, President, Caltech.
- Dr. Lennard Fisk, Associate Administrator, Office of Space Science and Applications, NASA.
- Dr. Paul Jennings, Vice President and Provost, Caltech.

The CSMT has formed a Scientific Advisory Board (SAB) to advise the CSMT Board of Governors, the CSMT Director, and JPL management on the content and quality of the CSMT technical program. The SAB consists of the following members:

- Dr. Terry Cole, Chief Technologist, JPL (Board Chairman).
- Dr. Bob L. Gregory, Director, Microelectronics/Materials Center, Polaroid Corporation.
- Professor Carver Mead, Department of Computer Science, Caltech.
Dr. Venkatesh Narayanamurti, Vice President for Research, Sandia National Laboratories.

Professor John Whinnery, Department of Electrical Engineering and Computer Science, University of California, Berkeley.

Dr. Jerry Woodall, Thomas J. Watson Research Center, IBM Corporation.

The SAB met twice during the past year to obtain an overview of CSMT activities. The SAB concluded that the facilities and capabilities of the CSMT form a sound combination for space microelectronics research and development work in the future. In addition, the staff was rated as "technically outstanding, enthusiastic, and well versed in [their] fields of specialization." All in all, the findings of the SAB are highly encouraging for the CSMT.

The CSMT encompasses four major research areas: solid state devices, photonics, computer architecture, and custom microcircuits. This Director's Report focuses on recent CSMT activities as well as the more significant achievements of the Center and its staff.

The past year has been a busy and productive time for the CSMT. The Center continues in a leadership role on a number of scientific, programmatic, and institutional fronts at JPL.

**Technical Achievements**

On the technical front, the CSMT has actively pursued research in a variety of areas. CSMT scientists and engineers have made great strides in several fields of endeavor, including the following:

- **Achievement of breakthrough performance for very long wavelength germanium blocked impurity band (GeBIB) detectors.** Initial data indicate high responsivity (4.5 amperes per watt at 100 microns), dark current of less than 1000 electrons per second, and spectral response to 200 microns. The detectors have achieved the far-infrared coverage, quantum efficiency, and dark current performance required by the Space Infrared Telescope Facility (SIRTF) mission.

- **Growth and fabrication of CoSi2 infrared detectors using silicon molecular beam epitaxy and a doping spike thereby increasing the cutoff wavelength from 3.5 to 5.0 microns.**

- **Demonstration of an InGaAsSb 2.1 micron laser for use in pumping solid state lasers for LIDAR and long-range optical communication.**

- **Development of nonlinear optical organic materials with second-harmonic efficiency ten times greater than the previous record.**

- **Design and fabrication of the custom direct memory access controller (DMAC) chip with 55,000 transitors.** The design meets flight qualification standards and the initial chip is fully functional. The DMAC is designed for the Mariner Mark II spacecraft computer.

- **Processing of Voyager 2 images from Neptune on an eight-node hypercube, with 80 times greater performance than that obtained using a VAX 8600 computer.** The images were used for "weather forecasting" of the motion of storms on Neptune, allowing detailed imaging during the close encounter period.
• Discovery and demonstration of a novel neural nets algorithm and architecture to solve computationally intensive problems such as resource allocation and the "Traveling Salesman Problem."

• Demonstration of a niobium nitride-based superconductor (SIS) tunnel junction as a mixer in a 205-GHz heterodyne receiver.

In the area of electron tunneling, William Kaiser's pioneering developments in electron tunneling including invention of ballistic electron emission microscopy (BEEM) (with L.D. Bell) have been rewarded with a NASA Outstanding Scientific Achievement Award. Dr. Heinrich Rohrer, IBM-Zurich Research Laboratory, visited JPL in order to discuss BEEM, which now allows for the study of buried interfaces. Dr. Rohrer was recipient of the 1986 Nobel Prize in Physics for the invention of the scanning tunneling microscope.

Programmatic Achievements

On the programmatic front, the CSMT has coordinated with the NASA Office of Aeronautics and Space Technology, the NASA Langley Research Center, and the NASA Ames Research Center to initiate a research program with AT&T Bell Laboratories on the applicability of multiple quantum well technology for NASA infrared focal plan array needs in the 6- to 17-micron range. Such technology is required for several JPL Earth Observing System (Eos) instruments, including the Atmospheric Infrared Sounder (AIRS).

A new effort in the area of high temperature superconductivity has been initiated within the CSMT by NASA. Brian Hunt's current effort in thin film superconductivity for SDIO/IST and DARPA is augmented. In addition, another effort directed by Donald Strayer focuses on the RF characterization of high temperature superconducting materials.

The U.S. Army Laboratory Command, which includes the Army Laboratories, the Army Research Office, and the Army Space Technology and Research Office, has become a CSMT sponsor. The CSMT program for the Army focuses on ballistic electron devices and millimeter wave imaging.

The CSMT has achieved progress in the transfer of technology to industry in the following areas:

• Electron tunneling accelerometer to the Charles Stark Draper Laboratory;

• Neural network technology to McDonell Douglas Corporation and TRW;

• Superconducting niobium nitride tunnel-junction wafers for circuit applications to TRW;

• Silicon-compatible infrared detector technology collaboration with Hughes; and,

• Collaborative development of a fault tolerant multiprocessor computer with Unisys.

The CSMT has participated extensively in planning sessions and program reviews for Center sponsors. It is a goal of the Center to have an overview of space microelectronics that includes both civilian and defense needs. CSMT personnel have served on the DARPA neural networks study team, participated in SDIO electronics and signal processing reviews, and worked with NASA to plan initiatives in high performance computing and global change technology. The CSMT Director represents NASA on the
Technical Review Committee for the Joint Services Electronics Program (JSEP). JSEP is an Army, Navy and Air Force program that funds electronics research at thirteen universities. The CSMT Director also served on the NASA team that evaluated proposals by 110 U.S. universities for establishment of NASA Space Engineering Research Centers. Nine universities were awarded centers. The two institutions selected in the area of space microelectronics are:

- The University of Michigan Center for Space Terahertz Technology; and,
- The University of Idaho Center for Custom VLSI for Space Applications.

The CSMT is working closely with the University of Michigan Center in a program in which CSMT scientists and Michigan faculty members collaborate in research on a wide range of topics, including quantum well multipliers, varactor multipliers, and quantum well negative resistance tunneling oscillators.

Also on the programmatic front, the CSMT has actively pursued its Distinguished Visiting Scientist (DVS) program, designed to allow outstanding researchers from industry and academia to interact and work with CSMT staff members. Recent DVS participants have included Erik Fossum, Columbia University; James Lukens, State University of New York, Stony Brook; Pieter Balk, Delft Institute of Technology, The Netherlands; Floyd Humphrey, Boston University; James Rosenberg, Brown University; Craig Davis, Ford Motor Company; James Mayer, Cornell University; and Olof Engstrom, Chalmers University, Sweden.

Institutional Achievements

On the Institutional front, the CSMT has several areas of accomplishments to report. Among the most exciting developments is the completion of the state-of-the-art Microdevices Laboratory (MDL); it is described in the following section.

The CSMT, with support from SDIO/Innovative Science and Technology Office, has acquired the JEOL JBX-5DII electron beam lithography system, offering a resolution unsurpassed by any other instrument of its kind. This facility allows the fabrication of devices with feature sizes as small as 15 nm. Structures and devices to be fabricated include quantum size effect dots, nanometer scale superconducting submillimeter wave detectors, a distributed feedback diode laser, and thin film neural network synapses.

Carl A. Kukkonen, Director
Microdevices Laboratory

Introduction

The new JPL Microdevices Laboratory (MDL), completed in 1989, is the primary facility of the Center for Space Microelectronics Technology (CSMT). It is dedicated to research and advanced development of microelectronic and photonic devices to meet the unique needs of NASA and DOD space missions. The Microdevices Laboratory will also significantly enhance JPL/Caltech campus collaborative research in the fields of electrical engineering and condensed matter physics.

The MDL enables the development of a multitude of advanced space microelectronic devices, such as infrared detectors, millimeter and submillimeter wave detectors, electronic neural network devices, lasers, and optoelectronic integrated circuits. Experimental solid state devices based on silicon, compound semiconductors and superconductors are fabricated and characterized for their electrical, optical and surface/interface properties in the MDL. Technology developed at the MDL will eventually be transferred to industry.

Building Facilities

The MDL is a 38,000 square foot facility with clean rooms for material deposition, lithography and device processing, and conventional laboratories for characterization. The clean rooms, divided into three categories (classes 10, 100, 1000) are arranged in conventional bays (work areas) and chases for mechanical pumps and utilities. These features are shown in the figure at the end of this section.

Located above the conventional laboratories are two levels of offices which accommodate the 65 scientists, engineers and staff of the MDL. The Microdevices Laboratory is designed to encourage a high level of intellectual synergism, and enable the benefits of sharing key equipment and experienced support staff.

The MDL meets all the Federal, State, and County safety codes and regulations. Toxic and pyrophoric gases are stored in autopurge gas cabinets in a gas bunker. These gases are distributed to the point of use by nitrogen gas-purged coaxial stainless steel pipes; and at the point of use, the valves and regulators are enclosed in exhausted secondary enclosures. Toxic and pyrophoric gases are continuously monitored by a sophisticated safety system that includes seismic sensors, and the MDL staff has received extensive safety training.

Research Equipment

The materials deposition capabilities of the MDL include silicon and compound semiconductor molecular beam epitaxy (MBE), metalorganic chemical vapor deposition (MOCVD), atomic layer epitaxy (ALE), liquid phase epitaxy (LPE), chemical vapor deposition (CVD) of amorphous silicon, sputtering, electron beam evaporation, and laser ablation used for high temperature superconductors.

Devices are fabricated using optical and electron beam lithography, diffusion and oxidation, and wet and dry etching. The MDL houses a state-of-the-art Electron Beam Lithography Laboratory in a class 10 clean room. The JEOL JBX-5DII e-beam lithography system can focus its writing beam down to an 8 nanometer diameter. It is expected that 40 nanometer (0.04 micron) structures will be the working norm for patterns created with the JBX-5DII.
The Electron Beam Lithography Laboratory also has a complete array of support equipment. Included are a JEOL IC-848 scanning electron microscope with an image processing attachment, a Zeiss Axiophot optical microscope with TV monitor and image processing capability, a Leitz MPV-SP film thickness measurement tool, a surface particle contamination measurement instrument, an airborne particle count measurement tool, Soletect spinners for coating and developing photoresist, a YES vacuum priming oven, several baking ovens and both acid and solvent wet benches.

Materials and devices are characterized using state-of-the-art electrical and optoelectronic techniques. Surfaces and interfaces are studied using photoemission, scanning auger microscopy (SAM), scanning electron microscopy (SEM), transmission electron microscopy (TEM), scanning tunneling microscopy (STM), and ballistic electron emission microscopy (BEEM).

Summary

The JPL Microdevices Laboratory is fully operational including the state-of-the-art JEOL electron beam lithography system. This facility enables the end-to-end fabrication of devices down to submicron feature size based on silicon, amorphous silicon, compound semiconductors, and superconductors. The MDL also has full capability for surface/interface and bulk electrical and optical characterization of materials and devices.
Overview

The Solid State Device Research Program is directed toward developing innovative devices for space remote and in-situ sensing, and for data processing. Innovative devices can result from the "standard" structures in innovative materials such as superconductors, strained-layer superlattices, or even metalloproteins. Innovative devices can also result from "innovative" structures achieved using electron tunneling or nanolithography in standard materials. A final step is to use both innovative structures and innovative materials.

The Solid State Device Research effort is housed in the new Microdevices Laboratory which is described in the introduction to the section, Microdevices Laboratory.

1988-1989 Major Technical Achievements

Electron Tunneling

- The new Ballistic Electron Emission Microscopy (BEEM) technique was invented and developed to enable many new capabilities for device structure diagnostics.
- BEEM enabled the first electron transport spectroscopy in semiconductor device structures which allows detailed characterization of the response of device components. Using BEEM, some of the most important material and interface factors limiting interface transport in devices were identified.
- BEEM methods were developed which enable direct measurement of subsurface interface band structure.
- BEEM was employed to identify defects in the important Au/GaAs Schottky barrier device structure. The origin of the defects was identified and the defects' dependence on device fabrication methods was determined.
- New device processing methods were developed which enabled all in-situ fabrication of metal/III-V Schottky device structures for the first time. The first ideal-interface Au/GaAs (100) Schottky barrier was fabricated using these methods.
- A prototype silicon micromachined tunnel position sensor was designed, fabricated and successfully tested. The tunnel accelerometer technology was transferred to the C.S. Draper Laboratory.

Superconductivity

- Designed and built high vacuum sputter deposition facility to deposit qualifiable NbN/MgO/NbN Superconductor-Insulator-Superconductor (SIS) mixer elements. The superconducting refractory, space transition temperature is 16 K.
- Fabricated NbN/AlN/NbN tunnel junctions. MgO barriers are superior.
- Designed and built low-temperature scanning tunneling microscope. Major accomplishments include:
- Observation of superconductor-vacuum-normal metal tunneling at high resolution and high tunneling resistance.

- First observation of superconductor phonon density of states effects using STM.

- First observation of superconductor vacuum-superconductor tunneling using low-temperature scanning tunneling microscope.

- Explored small area tunnel junction geometries. Edge geometry tunnel junctions were fabricated with areas down to 0.1 square microns.

- Fabricated high-quality NbN edge junctions on thin quartz and delivered for receiver testing. These are the first NbN edge junctions to undergo receiver testing. Test results indicated greater than a factor of 3 improvement in performance over previous devices, with a noise temperature of ~380 K at 205 GHz.

- Fabricated an array of NbN junctions that demonstrated remarkably good lateral uniformity, with only a 3% spatial deviation (1 sigma) in the critical current density across a 6 mm distance. Such uniformity is important for future applications requiring arrays and circuits in the NbN system.

- Transferred NbN/MgO/NbN technology to an industrial collaborator (TRW) to fabricate superconducting A/D converters for IR sensor readout circuits.

- Developed a bromine-based chemical etch for high-temperature superconducting YBa$_2$Cu$_3$O$_{7-x}$ films which removes the nonsuperconducting hydroxides and carbonates that form as a result of atmospheric exposure. This results in a stoichiometric, superconducting surface, which is important for future device applications of these thin films.

- Developed wet chemical techniques for passivation of YBa$_2$Cu$_3$O$_{7-x}$ against environmental degradation. Such techniques are critical for the avoidance of adverse effects on the performance of superconducting contacts, tunnel junctions, and other devices.

- Fabricated and tested YBaCuO/Au/Nb SNS device structures for electrical surface characterization of chemically-treated YBaCuO thin films. The tests indicated that high quality, superconducting surfaces can be obtained on YBa$_2$Cu$_3$O$_{7-x}$.

Submillimeter (Terahertz) Receiver Technology

- Fabricated InGaAs/AlAs quantum well resonant tunneling devices with a cutoff frequency near 1000 GHz. These devices are used as fundamental oscillators and frequency multipliers in submillimeter heterodyne receivers (1 mm = 300 GHz = 0.3 Thz).

- Demonstrated frequency multiplication to 200 GHz.

- Demonstrated fundamental oscillation at 425 GHz.
- **Developed** first NbN/MgO/NbN edge junction.
- **Fabricated** edge and mesa junctions with integral tuning stubs.
- **Tested** edge and mesa junctions as mixers at 200 GHz performance within a factor of 4 of best Pb alloy results.
- **Developed** planar antenna configuration for dielectrically filled parabola.
- **Demonstrated** Barrier-Intrinsic-N type (BIN) diode concept for submillimeter wave GaAs multiplier grids. Demonstrated (with UCLA) a 1 Watt, 100 GHz output from BIN diode arrays.
- **Developed** theoretical model of novel far-infrared laser, based on intersubband transitions in GaAs/AlGaAs quantum wells, with current injection. The model predicts feasibility of submillimeter radiation generation at moderate threshold currents for the 60 - 150 μm range.

**Semiconducting Materials: Growth and Characterization**

- **Demonstrated** for the first time the growth of diamond-like carbon thin films by electron cyclotron resonance plasma deposition. This technology has application to high temperature devices and to advanced optical coatings for sensor protection in space.
- **Demonstrated** growth of high-quality GaAs/AlGaAs structures on Si substrates by a combination of migration enhanced molecular beam epitaxy (MEMBE) and MOCVD techniques.
- **Demonstrated** for the first time the planar oxide maskless growth of GaAs on Si substrates by migration-enhanced molecular beam epitaxy (MEMBE) followed by transient-mode liquid phase epitaxy (TMLPE) in collaboration with the University of Florida.
- **Demonstrated** the first successful growth of single-crystal, pinhole-free CoSi₂ and IrSi₃. These materials are being used in ongoing work in Si-based Schottky-diode IR detectors.
- **Developed** a novel MOCVD process, enabling the first successful epitaxial growth of CdMgTe.
- **Demonstrated** growth of detector quality InAs thick films on GaAs (100) substrates.
- **Demonstrated** growth of InAs quantum wells strained to match the GaAs lattice constant. With new stoichiometry control techniques, obtained quantum well luminescence intensities up to 8 times greater than those for the bulk GaAs reference quantum wells for well thicknesses from 1 to 4 monolayers.
Electronic Device Technology

- **Established** a state-of-the-art Electron Beam Lithography Laboratory, comprised of a JEOL JBX-5DII e-beam lithography system, JEOL IO-848 scanning electron microscope complete with image processing equipment, a Zeiss microscope, a Leitz film thickness measurement tool, PMS surface particle contamination and airborne particle count instruments, and related photoresist processing equipment, all housed in a Class 10 clean room bay of the Microdevices Laboratory. The JEOL JBX-5DII has greater resolution than any other commercially available e-beam lithography system, and is capable of generating a probe beam only 8 nanometers in diameter.

- **Made operational** the photodetachment atomic oxygen source. This is the only source in the world capable of delivering a pure, ground-state beam of atomic oxygen, with a variable energy in the range 2-50 eV, and a flux comparable to that encountered by spacecraft in low earth orbit.

- **Demonstrated** that an oxide layer could be formed on SiO2 by room-temperature exposure to a low-energy O" beam. The O" beam is several orders of magnitude more reactive than a comparable beam of O2.

- **Fabricated** high-gain AlGaAs intrinsic-base and Zn-diffused extrinsic-base double heterojunction bipolar transistors (DHBTs) grown by MOCVD. Single transistors exhibited a current gain of 500-750 at a collector current density of 500 A/cm² and their Darlington transistor pairs showed current gains up to 5000.

Molecular Electronics

- **Demonstrated** self-orientation of proteins relative to a surface by utilizing X-ray photoelectron spectroscopy (XPS) in conjunction with a novel myoglobin derivative.
**Electron Tunneling**

**Publications**

"Observations of Interface Bandstructure by Ballistic-Electron-Emission Microscopy"
L. D. Bell, W. J. Kaiser

"Spatially Resolved Ballistic Electron Spectroscopy of Subsurface Interfaces"
L. D. Bell, W. J. Kaiser
J. Microscopy 152, 605 (1988)

"Scanning Tunneling Microscopy Methods for Spectroscopic Imaging of Subsurface Interfaces"
L. D. Bell, W. J. Kaiser
Scanning Microscopy, 2, 1231 (1988)

"Process Dependent Morphology of the Si/SiO2 Interface Measured with STM in SiO2 and its Interfaces"
M. H. Hecht, L. D. Bell, F. J. Grunthaner, W. J. Kaiser

"Superconducting Phonon Spectroscopy using a Low-Temperature Scanning Tunneling Microscope"
H. G. LeDuc, W. J. Kaiser, B. D. Hunt, L. D. Bell, R. C. Jaklevic, M. G. Youngquist

"An Electron Tunneling Sensor"
S. B. Waltman, W. J. Kaiser
Sensors and Actuators, 19, 201 (1989)

"Electron Tunnel Sensor Technology"
S. B. Waltman, W. J. Kaiser

"Direct Investigation of Subsurface Interface Electronic Structure by Ballistic Electron Emission Microscopy"
W. J. Kaiser, L. D. Bell

"Ballistic-Electron-Emission Microscopy and Spectroscopy of Au-GaAs Interfaces"
W. J. Kaiser, L. D. Bell, M. H. Hecht, F. J. Grunthaner

"Ballistic-Electron-Emission Microscopy and Spectroscopy of Au/GaAs Interfaces"
W. J. Kaiser, M. H. Hecht, L. D. Bell, F. J. Grunthaner

"Ballistic-Electron-Emission Microscopy Investigation of Schottky Barrier Interface Formation"
M. H. Hecht, L. D. Bell, W. J. Kaiser, F. J. Grunthaner
"Ballistic-Electron-Emission Microscopy Investigation of Schottky Barrier Interface Formation"
M.H. Hecht, L.D. Bell, W.J. Kaiser, F.J. Grunthaner

"Ballistic-Electron-Emission Microscopy of Subsurface Defects at the Au/GaAs (100) Interface"
M.H. Hecht, L.D. Bell, W.J. Kaiser
Applied Surf. Sci. (accepted for publication)

Presentations

"Imaging Subsurface Interfaces by Ballistic Electron Emission Microscopy"
L. D. Bell
Invited presentation at the Electrochemical Society Meeting, Chicago, October 10-14, 1988

"Direct Imaging of Subsurface Interface Properties by Ballistic Electron Emission Microscopy"
L. D. Bell, W. J. Kaiser
Scanning Tunneling Microscopy Conference, Oxford, UK, July 4-8, 1988

"Interface Imaging by BEEM"
L. D. Bell
Invited presentation at joint APS/AAPT Symposium on STM, San Francisco, CA, January, 14-19, 1989

"BEEM"
L. D. Bell
Invited presentation, STM '89, Oarai, Japan, July 10-14, 1989

"Ballistic Electron-Emission Microscopy: Scanning Tunneling Microscopy Applied to Subsurface Interfaces"
L.D. Bell
Invited presentation, Physics Department Seminar, Rensalaer Polytechnic Institute, NY, October, 1989

"Ballistic Electron-Emission Microscopy of Semiconductor Interface Structure"
L.D. Bell
Invited presentation, New York Chapter of the American Physical Society, Symposium on STM, October, 1989

"Ballistic-Electron-Emission Microscopy and Spectroscopy of Au-GaAs Interfaces"
L. D. Bell, M. H. Hecht, and W. J. Kaiser
Invited presentation at Physics and Chemistry of Semiconductor Interfaces Meeting, Bozeman, MT, February 7-9, 1989

"Ballistic Electron Emission Microscopy and Spectroscopy of Subsurface Interfaces"
L. D. Bell
Invited presentation, Cal. State Northridge, Northridge, CA, March 8, 1989
"Scanning Tunneling Microscopy Investigation of Semiconductor Surfaces and Interfaces"
W.J. Kaiser
Invited presentation, Solid State Sciences Seminar at Sandia National Laboratories,
February 12, 1988

"Scanning Tunneling Microscopy Investigation of Semiconductor Interfaces"
W.J. Kaiser
Invited presentation, American Physical Society Meeting, April 21, 1988

"Scanning Tunneling Microscopy Investigation of Semiconductor Surfaces and Interfaces"
W.J. Kaiser
Invited presentation, Scanning Microscopy Meeting, May 2, 1988

"Subsurface Interface Imaging by Ballistic Electron Emission Microscopy"
W.J. Kaiser
Invited presentation, Naval Research Laboratory, August 29, 1988

"Spectroscopic Probing of Semiconductor Interface Structure with Nanometer Spatial Resolution"
W. J. Kaiser
Invited presentation at 2nd International Conference on the Formation of Semiconductor Interfaces (ICSFI), Osaka, Japan, November 8-12, 1988

"Spectroscopic Probing of Semiconductor Interface Structure with Nanometer Spatial Resolution"
W. J. Kaiser
Invited presentation, Applied Physics Seminar, California Institute of Technology,
Pasadena, CA, November 15, 1988

"Subsurface Interface Imaging by Ballistic Electron Emission Microscopy"
W. J. Kaiser
Invited presentation at the Naval Research Laboratory, August 29, 1988

"Spectroscopic Probing of Subsurface Interface Properties with Nanometer-Scale Resolution"
W. J. Kaiser

"Spectroscopic Probing of Semiconductor Interface Structure with Nanometer Spatial Resolution"
W. J. Kaiser
Invited presentation, Applied Physics Seminar, California Institute of Technology,
Pasadena, CA, November 15, 1988

"Ballistic Electron Emission Spectroscopy"
W. J. Kaiser
AVS Thin Film and Surface Science Open House, Jet Propulsion Laboratory, California Institute of Technology, Pasadena, CA, January 23, 1989

"Ballistic Electron Emission Spectroscopy"
W. J. Kaiser
Invited presentation, American Physical Society Meeting, St. Louis, MO, March 20-24, 1989
"BEEM: A Nanometer-Resolution Probe of Subsurface Interfaces"
W. J. Kaiser
*Invited* presentation, SEM 1989 Meeting, Long Beach, CA, April 7-9, 1989

"Ballistic-Electron-Emission Microscopy Investigation of Semiconductor Interfaces"
W. J. Kaiser, L. D. Bell, M. H. Hecht
*Invited* presentation, Semiconductor Sciences Seminar, IBM T. J. Watson Research Center, Yorktown Heights, NY, May 24, 1989

"Ballistic-Electron-Emission Microscopy Investigation of Semiconductor Interfaces"
W. J. Kaiser, L. D. Bell, M. H. Hecht
*Invited* presentation, Interface Science Seminar, National Institute of Standards and Technology, Gaithersburg, MD, May 25, 1989

"Scanning Tunneling Microscopy Investigation of Semiconductor Interfaces"
W. J. Kaiser
*Invited* presentation, International Vacuum Congress, Cologne, Germany, September, 1989

"Ballistic-Electron Emission Microscopy: Imaging and Spectroscopy of Subsurface Interfaces"
W. J. Kaiser
*Invited* presentation, IBM, Zurich Research Laboratory, October, 1989

"Ballistic-Electron Emission Microscopy: Imaging and Spectroscopy of Subsurface Interfaces"
W. J. Kaiser
*Invited* presentation, Physics Department Seminar, Cornell University, Ithaca, NY., November 21, 1989

"Semiconductor Interface Electronic Structure Investigation by Ballistic-Electron-Emission Microscopy"
W. J. Kaiser
*Invited* presentation, Materials Research Society Meeting, Boston, MA., November 27-December 2, 1989

"Electron Tunnel Sensors"
S. B. Waltman, W. J. Kaiser
Vacuum Microelectronics Conference, Williamsburg, VA, June 13-17, 1988

"Schottky Diode Characteristics, Surface Chemistry, and Surface Structure on Melt-Grown and MBE-Grown GaAs(100) Surfaces"
M. H. Hecht, L. D. Bell, F. J. Grunthaner, W. J. Kaiser
PCSI Meeting, Physics and Chemistry of Semiconductor Interfaces Meeting, Bozeman, MT, February 7-9, 1989

"Ballistic Electron Emission Microscopy of Au/GaAs Interfaces"
M. H. Hecht
*Invited* presentation, Colorado School of Mines, Golden, CO, February 6-9, 1989

"Ballistic-Electron Emission Microscopy Investigation of Semiconductor Interfaces"
M. H. Hecht
"Ballistic Emission Spectroscopy AlAs Quantum Structures"
M. H. Hecht
STM '89, Oarai, Japan, July 10-24, 1989

"Interface Chemistry and Electrical Characteristics of Au Schottky Diodes Formed In-situ on Melt-Grown and Molecular-Beam-Epitaxy-Grown GaAs (100) Surfaces"
M. H. Hecht, L. D. Bell, W. J. Kaiser, F. J. Grunthaner
American Physical Society Meeting, St. Louis, MO, March 20-24, 1989

"Ballistic-Electron-Emission Microscopy Investigation of Semiconductor Interfaces"
M. H. Hecht

"The Observation of Superconductor-Superconductor Tunneling Using a Low-Temperature Scanning Tunneling Microscope"
H. G. LeDuc, W. J. Kaiser, L. D. Bell
American Physical Society Meeting, St. Louis, MO, March 20-24, 1989

Patents and New Technology Reports

"Ballistic Electron Emission Microscope (BEEM)"
W. J. Kaiser, L. D. Bell
NASA Tech Brief NPO-17384
U. S. Patent No. 4,823,004

"Tunnel Effect Displacement Sensor"
W. J. Kaiser, S. B. Waltman
NASA Tech Brief NPO-17362

"Epitaxial Diffusion Barriers for Schottky Barrier Formation and Interdiffusion Control on Epitaxial Gallium Arsenide Films"
W. J. Kaiser, F. J. Grunthaner, L. D. Bell, M. H. Hecht
NPO-17796

"Formation of Room Temperature Ohmic Contacts on Epitaxial Gallium Arsenide Films"
L. D. Bell, M. H. Hecht, W. J. Kaiser
NPO-17795
Superconductivity

Publications

"NbN/MgO/NbN SIS Tunnel Junctions for Submm Wave Mixers"

"NbN/MgO/NbN Edge-Geometry Tunnel Junctions"

"Superconducting Phonon Spectroscopy Using a Low-Temperature Scanning Tunneling Microscope"
H.G. LeDuc, W.J. Kaiser, B.D. Hunt, L.D. Bell, R.C. Jaklevic, M.G. Youngquist
Applied Physics Letters (submitted)

"Y-Ba-Cu-O Superconducting Thin Films by Simultaneous or Sequential Evaporation"
A. Mogro-Campero, B. D. Hunt, L. G. Turner, M. Burrell, W. E. Balz

"Superconducting Y-Ba-Cu-O Films by Evaporation"
A. Mogro-Campero, B. D. Hunt, L. G. Turner, M. C. Burrell, W. E. Balz

"A Nonaqueous Chemical Etch for YBa2Cu3O7-x"
R. P. Vasquez, B. D. Hunt, M. C. Foote

"A Nonaqueous Chemical Etch for YBa2Cu3O7-x"
R. P. Vasquez, B. D. Hunt, M. C. Foote
Proceedings of the AVS Topical Conference on Superconducting Thin Films, Devices, and Characterization; October 3, 1988, Atlanta, Georgia, AIP Conference Proceedings #182, p 376

"Nonaqueous Chemical Depth Profiling of YBa2Cu3O7-x"
R. P. Vasquez, M. C. Foote, B. D. Hunt

"Reduced Reactivity to Air on HF-treated YBa2Cu3O7-x Surfaces"
R. P. Vasquez, B. D. Hunt, M. C. Foote

"Wet Chemical Etching Techniques for Passivation of YBaCuO"
R. P. Vasquez, M. C. Foote, B. D. Hunt

"Wet Chemical Techniques for Passivation of YBaCuO"
R. P. Vasquez, M. C. Foote, B. D. Hunt
Proceedings of the American Vacuum Society Conference, Boston, MA, October 23, 1989
"Wet Chemical Passivation of YBaCuO"
R.P. Vasquez, B.D. Hunt, M.C. Foote

"Electrical Contact Studies of Chemically Treated YBaCuO Surfaces"
B.D. Hunt, M.C. Foote, R.P. Vasquez
American Vacuum Society Conference Proceedings, Boston, MA, October 23, 1989

"XPS Core Level Spectra of Some Y Compounds"
R. P. Vasquez
Journal of Electron Spectroscopy (accepted for publication)

"Reaction of Nonaqueous Halogen Solutions with YBa2Cu3O7"
M.C. Foote, B.D. Hunt
Journal of Applied Physics, November, 1989

"Growth and Characterization of Large YBa2Cu3O7-x Single Crystals"

"Syntactic Intergrowth Problems with BCSCO and Fabrication Difficulties Therefrom"
P.E.D. Morgan, J.J. Ratto, R.M. Housely, J.R. Porter

"Synthesis Variability and Syntactic Intergrowths in the BCSCO System:
J.J. Ratto, R.M. Housely, J.R. Porter, P.E.D. Morgan

"Ceramic Problems/Challenges in High Temperature Oxide Superconductors, Hysteretic
Force Measurements as a New Analysis Tool"
International Superconductivity Symposium, Nagoya, Japan, August, 1988

"Low Activation Energy Damage in Ion Bombarded YBa2Cu3O7-x Thin Films"
I.S. Gergis, P.H. Kobrin, J.F. DeNatale, R.M. Housely
Rockwell Science Center, Thousand Oaks, CA

Presentations

"NbN/MgO/NbN SIS Tunnel Junction for Submm Wave Mixers"

"Superconducting Devices"
H. G. LeDuc
AVS Thin Film and Surface Science Open House, Jet Propulsion Laboratory, California
Institute of Technology, Pasadena, CA, January 23, 1989
"Investigation of High Tc Superconducting Thin Films for Device Applications"
B. D. Hunt, M. C. Foote, R. P. Vasquez, H. G. LeDuc, D. M. Stayer
DARPA High Temperature Superconductor Conference, Washington, D.C., September 13, 1988

"NbN/MgO/NbN Edge Junctions"
B. D. Hunt, H. G. LeDuc, S. R. Cypher
American Physical Society Meeting, St. Louis, MO, March 20-24, 1989

"Electrical Characterization of Chemically-Modified YBa2Cu3O7-x"
B. D. Hunt, M. C. Foote, R. P. Vasquez, H. G. LeDuc, W. J. Kaiser
Materials Research Society Meeting, San Diego, April 24-28, 1989

"NbN/MgO/NbN Edge Junction: Fabrication and SIS Mixer Results"
Invited presentation, Superconductive Electronics Workshop, St. Michael's MD, October 2, 1989

"Electrical Contact Studies of Chemically Treated YBa2Cu3O7-x Surfaces"
B. D. Hunt, M. C. Foote, R. P. Vasquez

"NbN Edge Junctions and Electrical Characterization of Chemically Modified YBaCuO Thin Film Surfaces"
B. D. Hunt
Invited presentation, IBM T.J. Watson Research Center, Yorktown Heights, NY, August 8, 1989

"High-Temperature Superconductor Thin Film Devices"
B. D. Hunt
NASA Program Review of High-temperature Superconductor Work Within NASA, Goddard Space Flight Center, Greenbelt, MD, August 29, 1989

"Exploratory Study in Making As-Deposited YBa2Cu3O7-x Films Using a BaF2 Source"
M. C. Foote, B. D. Hunt, R. Livi, P. Haubert, M. Dobeli, T. A. Tombrello, D. L. Goodstein
SEM 1989 Meeting, Long Beach, CA, April 5-7, 1989

"Surface Characterization of As-Deposited, Post-Annealed, and Chemically Modified YBa2Cu3O7-x Films"
M. C. Foote, B. D. Hunt, R. P. Vasquez
American Physical Society Meeting, St. Louis, MO, March 20-24, 1989

"A Nonaqueous Chemical Etch for YBaCu"
R. P. Vasquez, B. D. Hunt, M. C. Foote
American Vacuum Society Meeting, New Orleans, LA, October 3, 1988

"Reactions of Nonaqueous Halogen Solutions with YBa2Cu3O7-x"
R. P. Vasquez, M. C. Foote, B. D. Hunt
Materials Research Society Meeting, San Diego, CA, April 24-28, 1989
"Wet Chemical Techniques for Passivation of YBa$_2$Cu$_3$O$_{7-x}$"
R. P. Vasquez, B. D. Hunt, M. C. Foote

"Evolution of Layered High Temperature Superconducting Oxide Precursor Films Under High Energy Heavy Ion Bombardment"
M.C. Foote, R.D. Hunt, R. Livi, P. Haubert, M. Dobeli, T.A. Tombrello, R.M. Housely, D.L. Goodstein
Scanning 89/EM West Conference, Long Beach, CA, 1989

"New Approaches to Monitoring the Preparation and Properties of High T$_c$ Superconductors"
MRS Spring Conference, San Diego, CA, 1989

"Monitoring Sintering/Densification and Crystallization/Grain Growth in Tl-Based High Temperature Superconductors by Electrical Resistance Measurements"
J.J. Ratto, J.R. Porter, R.M. Housely, P.E.D. Morgan
MRS Fall Conference, Boston, MA, 1989

"Scanning Electron Microscope and Heavy Ion RBS Characterization of Thin Bi-Sr-Ca-Cu-O Films"
R.M. Housely, P. Kobrin, A. Harker, P. Haubert, M. Dobeli, R. Livi, D.L. Goodstein, T. Tombrello
Scanning 89/EM West Conference, Long Beach, CA, 1989

"Critical Currents in Highly Oriented Melt Deposited Films of Bi$_2$Sr$_2$CaCu$_2$O$_8$
R.M. Housely, P.E.D. Morgan, J.J. Ratto, I.B. Goldberg
Rockwell International Science Center, Thousand Oaks, CA
MRS Spring Conference, 1990 (submitted)

Patents and New Technology Reports

"Surface Halogenation of High-Temperature Superconductors"
R. P. Vasquez
NASA Tech Brief NPO-17712

"Long Wavelength Infrared Detector"
R.P. Vasquez
NASA Tech Brief NPO-17543 (patent pending)

"Oxidation of Semiconductors and Superconductors"
R.P. Vasquez
NASA Tech Brief NPO-17534 (patent pending)
Submillimeter (Terahertz) Receiver Technology

Publications

"NbN/MgO/NbN SIS Tunnel Junctions for Submm Wave Mixers"

"Fundamental Oscillations Up to 200 GHz in Resonant Tunneling Diodes and New Estimates of Their Maximum Oscillation Frequency from Stationary-State Tunneling Theory"
E. R. Brown, W. D. Goodhue, T. C. L. G. Sollner

"Harmonic Multiplication Using Resonant Tunneling"
T. C. L. G. Sollner, E. R. Brown, W. D. Goodhue, C. A. Correa
J. Appl. Phys. 64, p. 4248 (1988)

"Microwave and Millimeter-Wave Resonant-Tunneling Devices"
T. C. L. G. Sollner, E. R. Brown, H. Q. Le

"Effects of Quasibound-states Lifetime on the Oscillation Power of Resonant Tunneling Diodes"
E. R. Brown, C. D. Parker, T. C. L. G. Sollner

"Experimental Results of a High Q Quasioptical Reflection Cavity"
K. A. Lee, M.A. Frerking

"The Dielectric-Filled Parabola: A New Millimeter/Submillimeter Wavelength Receiver/Transmitter Front End"
P. H. Siegel

"Measurements of Dipole, Bow-Tie, Log-Periodic and Log-Spiral Antennas on a Dielectric-Filled Parabola"
P. H. Siegel

"Oscillations up to 420 GHz in GaAs/AlAs Resonant-Tunneling Diodes"
E. R. Brown, T. C. L. G. Sollner, C. D. Parker, W. D. Goodhue, C. L. Chen

"Evaluation of the Feasibility of a Far Infrared Laser Based on Intersubband Transitions in GaAs Quantum Wells"
S. Borenstain, J. Katz
Presentations

"Quantum Well Multipliers"
P. D. Batelaan, M. A. Frerking

"A Quantum-Well Frequency Multiplier with Millimeter-Wave Output"
P. D. Batelaan, M. A. Frerking

"Theoretical Performance of Quantum Well Multipliers"
M.A. Frerking
Solid State THz Sources Workshop, Pasadena, CA, August 1988

"A Novel Noncontacting Waveguide Backshort Design for Millimeter and Submillimeter Wave Frequencies"
W. R. McGrath
IEEE MTT-S International Microwave Symposium, Dallas, TX (1990) (submitted)

"205 GHz SIS Receiver Development"
W. R. McGrath, C. N. Byrom, B. N. Ellison, M. A. Frerking, H. G. Leduc, R. E. Miller, J. A. Stern
Digest Int. Symp. Submm & mm Astron., Kona, HI, 3--6 October, 1988

"205 GHz SIS Receiver Development for Remote Sensing Applications"
W. R. McGrath, C. N. Byrom, B. N. Ellison, M. A. Frerking, R. E. Miller

"Large Scale Modeling of a Submillimeter Wave SIS Mixer with Integrated Tuning Elements"
K. Jacobs, W. R. McGrath

"Measurements of Dipole, Bow-tie, Log-Periodic and Log-Spiral Antennas on a Dielectric-Filled Parabola"
P. H. Siegel, R. J. Dengler

"The Dielectric-Filled Parabola: A New High Frequency Integrated Receiver or Transmitter Front End"
P. H. Siegel, M. A. Frerking
"A Technique for Fabricating Free Standing Electrically Thick Metallic Mesh and Parallel Wire Grids for Use as Submillimeter Wavelength Filters and Polarizers"
P. H. Siegel, J. A. Lichtenberger
IEEE MTT Symposium (October, 1989)

"B-I-N Diodes"
U. Lieneweg
Presented at Solid State THz Sources Workshop, Pasadena, CA, August, 1988

Patents and New Technology Reports

"Millimeter and Submillimeter Wave Quantum Well Frequency Multipliers"
P.D. Batelaan, M.A. Frerking
NASA Tech Brief NPO-17584

"Planar Antennas on Thick Dielectrics Substrates"
K. A. Lee, M.A. Frerking
NASA Tech Brief NPO-17466

"High Q Quasi-Optical Tunable Resonator"
K.A. Lee, M.A. Frerking
NPO-17919 (patent pending)

"A New Noncontacting Waveguide Backshort Design Employing a Novel Geometry"
W. R. McGrath
NPO-18091

"Dielectric Filled Parabola With Integrated Planar Antenna for Use as a Millimeter/Submillimeter Wavelength Receiver/Transmitter Front End"
P. H. Siegel
NPO-17802

"A Technique for Fabricating Electrically Thick Free Standing Metallic Mesh for Use at Submillimeter Wavelengths"
P. H. Siegel, J. A. Lichtenberger
NPO-17992

"Self-Operating Range Charger for Computer Interfacing the HP415E SWR Meter"
R. J. Dengler, P. H. Siegel
NPO-17822

"Infrared Multiquantum Well Phototransistor"
S. Borenstain
NPO-17980
Semiconducting Materials: Growth and Characterization

Publications

"Growth of Single-Crystal Columns of CoSi2 Embedded in Epitaxial Si on Si (111)"
R.W. Fathauer, C.W. Nieh, Q.F. Xiao, S. Hashimoto

"Heavily Boron-Doped Si Layers Grown Below 700 °C by Molecular Beam Epitaxy"
T.L. Lin, R.W. Fathauer, P.J. Grunthaner

"Characterization of Si/CoSi2/Si (111) Heterostructures Using Auger Plasmon Losses"
F.D. Schowengerdt, L.T. Lin, R.W. Fathauer, P.J. Grunthaner

"Diffusion of Si on Thin CoSi2 Layers"
F.D. Schowengerdt, L.T. Lin, R.W. Fathauer, P.J. Grunthaner

"Growth of Epitaxial CoSi2/Si Multilayers"
B. D. Hunt
In Properties of Silicon, Inspec, New York, 1988, p 1001

"Growth of Si/CoSi2/Si Heterostructures"
B. D. Hunt
Properties of Silicon, Inspec, New York, 1988, p 1039

"Optical Properties of Epitaxial CoSi2 and NiSi2 Films on Silicon"
Grunthaner, and T. L. Lin

"Structural Properties of Epitaxial NiSi2 on Si(111) Investigated with X-ray Standing Waves"
J. Zegenhegen, K. G. Huang, W. M. Gibson, B. D. Hunt, And L. J. Schowalter

"Novel Photovoltaic δ-doped GaAs Superlattice Structure"
A.M. Glass, E.F. Schubert, B.A. Wilson, C.E. Bonner, J.E. Cunningham, D.H. Olson,
W. Jan

"Historical Perspective on Tunneling in SiO2"
J.Maserjian

"Transient-Mode Liquid Phase Epitaxial Growth of GaAs on GaAs-Coated Si Substrates Prepared by Migration-Enhanced Molecular Beam Epitaxy"
S. Nakamura, S.Sakai, S.S. Chang, R.V. Ramaswamy, J.H. Kim, G. Radhakrishnan,
J.K. Liu, and J.Katz
"High Efficiency CdTe Thin-film Solar Cells Using Metalorganic Chemical Vapor Deposition Techniques"
A. Nouhi, R.J. Stirn

"Γ to X Transport of Photoexcited Electrons in Type II GaAs/AlAs Multiple Quantum Well Structures"
P. Saeta, B.I. Green, R. Fischer, R.C. Spitzer and B.A. Wilson

"Growth and Characterization of Single Crystal Insulators on Silicon"
L.J. Schowalter, R.W. Fathauer

"Radiative Recombination Mechanisms in Staggered-Alignment (GaAs)/(AlAs) Heterostructures"
B.A. Wilson, C.E. Bonner, R.C. Spitzer, R. Fischer, P. Dawson, K.J. Moore, and C.T. Foxon

"Novel Applications of Optical Techniques to the Study of Buried Semiconductor Interfaces"
B.A. Wilson

"Temperature Control and Calibration Issues in the Growth, Processing and Characterization of Electronic Material"
B.A. Wilson

"Oxidation of Silicon with a 5 eV O⁻ Beam"
M. H. Hecht, O. J. Orient, A. Chutjian, R. P. Vasquez

"Growth and Characterization of GaAs on Si Substrates by Migration-enhanced Molecular Beam Epitaxy"

"Characteristics of Annealed p/n Junctions between GaAs and Si (100)"
H. Morkoc, G. Radhakrishnan, J. Katz, et. al.

"Molecular Beam Epitaxy and Metalorganic Chemical Vapor Deposition Growth of Epitaxial CdTe on (100) GaAs/Si and (111) GaAs/Si Substrates"
A.Nouhi, G.Radhakrishnan, J. Katz, K. Koliwad
"Laser-Assisted Molecular Beam Epitaxial Growth of GaAs on Si (100)"
S. Guha, F. J. Grunthaner, A. Madhukar, J. K. Liu, P. D. Lao, W. C. Tang, P. Andersson, J. Iannelli, B. Pate

"Extended Fine Structure Analysis of the Electron Energy Loss Spectrum of InAs/GaAs Strained Layer Quantum Wells"
F. D. Schowengerdt, F. J. Grunthaner

"Migration-Enhanced Molecular Beam Epitaxial Growth and Characterization of GaAs on Si Substrates"
J.H. Kim, S. Sakai, J.K. Liu, G. Radhakrishnan, S.S. Chang, J. Katz

Presentations

"Production of Epitaxial Columns of CoSi2 in a Single-Crystal Silicon Matrix Using MBE"
R.W. Fathauer, C.W. Nieh, Q.F. Xiao, S. Hashimoto
European MRS, Strasbourg, France, May 30-June 2, 1989

"Topics in Molecular Beam Epitaxy of Metal Silicides"
R.W. Fathauer
Invited presentation, Philips Research Laboratory, Eindhoven, The Netherlands, June 12, 1989

"Topics in Molecular Beam Epitaxy of Metal Silicides"
R.W. Fathauer
Invited presentation, Swiss Federal Institute of Technology, Zurich, Switzerland, June 5, 1989

"Reduction of the Effective Barrier Height in Epitaxial CoSi2/Si (111) Diodes by Selective Doping from an HBO2 Source"
R.W. Fathauer, T.L. Lin, J.M. Iannelli, P.J. Grunthaner, J. Maserjian
Fall MRS Meeting, Boston, MA, December, 1989

"Growth of CdTe Thin Films on Polar and Non-Polar Semiconductor Substrates by Metalorganic Chemical Vapor Deposition"
P. Grodzinsk, J.H. Mazur, A. Nouhi, R.J. Stirn
MRS Fall Meeting, Boston, MA, November 28, 1989

"Ion Channeling Studies of Single-Crystal Columns of CoSi2 Embedded in Epitaxial Si on Si (111) Grown by MBE"
S. Hashimoto, Q.F. Xiao, W.M. Gibson, C.W. Nieh, R.W. Fathauer

"Optical Properties and Electron Transport Across Interfaces in CoSi2/Si and NiSi2/Si"
APS Meeting, St. Louis, March, 1989
"Growth of Iridium Silicide by MBE"
T.L. Lin, C.W. Nieh (Caltech), S. Hashimoto
European MRS, Strasbourg, France, May 30-June 2, 1989

"Growth of Heavily Boron-Doped Oxygen-Free Silicon Layers by MBE Using a Metabolic Acid Source"
T.L. Lin, R.W. Fathauer, P.J. Grunthaner
European MRS, Strasbourg, France, May 30-June 2, 1989

"MBE Growth of Iridium Silicide"
T.L. Lin
Invited presentation, Swiss Federal Institute of Technology, Zurich, Switzerland, June 5, 1989

"Electron-Induced Epitaxial Growth of CoSi2 on (111) Si"
C.W. Nieh, T.L. Lin, and R.W. Fathauer
1989 MRS Spring Meeting, San Diego, CA, April 24-28, 1989

"Interlayer Transport of Photoexcited Electrons in Type II GaAs/AlAs Multiple Quantum Well Structures"
P.Saeta, R.J. Fischer, B.I. Greene, R.C. Spitzer, B.A. Wilson
CLEO/QELS Meeting, Baltimore, MD, April 24-28, 1989

"Si Diffusion in MBE-Grown CoSi2/Si (111) Heterostructures"
F.D. Schowengerdt, T.L. Lin, R.W. Fathauer, P.J. Grunthaner

"Long-Lived Metastable States in Novel GaAs Heterostructures"
R.C. Spitzer, B.A. Wilson, C.E. Bonner, L. Pfeiffer, A. M. Glass
CLEO/QELS Meeting, Baltimore, MD, April 24-28, 1989

"Electro-Optical Properties of GaAs/AlGaAs/AlAs/AlGaAs Staggered Alignment Heterostructures"
R.C. Spitzer, B.A. Wilson, C.E. Bonner, A.M. Glass
March, APS Meeting, St. Louis, MO, March, 1989

"Temperature Control and Calibration Issues in the Growth, Processing and Characterization of Electronic Materials"
B.A. Wilson
NASA Workshop on Non-Contact Thermal Measurement, Pasadena, CA, January 17-19, 1989

"Electro-Optical Properties of Staggered-Alignment AlGaAs Heterostructures"
B.A. Wilson
Invited presentation, CLEO/QELS Meeting, Baltimore, MD, April 24-28, 1989

"Optoelectronic Properties of Staggered-Alignment AlGaAs Heterostructures"
B.A. Wilson, R.C. Spitzer, C.E. Bonner, L. Pfeiffer
March, APS Meeting, St. Louis, MO, March, 1989
"Novel Applications of Optics: The Determination of Structural and Electronic Properties of Buried Semiconductor Interfaces"
B.A. Wilson
*Invited* presentation, Ontario Laser and Lightwave Research Center, University of Toronto, Canada, February 28, 1989

"Novel Applications of Optics: The Determination of Electronic and Structural Properties of Buried Semiconductor Interfaces"
B.A. Wilson
*Invited* presentation, SPIE Symposium on Raman Scattering, Luminescence and Spectroscopic Instrumentation on Technology, Los Angeles, CA, January 14-19, 1989

"Oxidation of Silicon with 5 eV O\(^{-}\) Beam"
M. H. Hecht, O. J. Orient, A. Chutjian, R. P. Vasquez
IEEE Semiconductor Interface Specialists Conference, San Diego, CA, December 7-10, 1988

"Applied Surface and Interface Analysis"
M. H. Hecht
AVS Thin Film and Surface Science Open House, Jet Propulsion Laboratory, California Institute of Technology, Pasadena, CA, January 23, 1989

"Epitaxial Growth Experiments of (100) GaAs/Si and (111) GaAs/Si Using Molecular Beam Epitaxy and Metalorganic Chemical Vapor Deposition"
G. Radhakrishnan, A. Nouhi, J. Liu
SPIE OE/LASE '88, Los Angeles, January 11-15, 1988

"Heteroepitaxy of CdTe on GaAs-on-Si"
G. Radhakrishnan, A.M. Nouhi, J. Katz
Conference on Heterostructures on Si: One Step Further with Si, Cargese, Corsica, May 6-10, 1988

"Extended Fine Structure Analysis of the Electron Energy Loss Spectrum of InAs/GaAs Strained Layer Quantum Wells"
F. D. Schowengerdt, F. J. Grunthaner
1988 Fall National Meeting of the Materials Research Society, Boston, MA, November 28-December 2, 1988

"AES Analysis and RHEED Control of Growth Front Morphology in InAs Strained Layer Epitaxy"
F. J. Grunthaner, F. D. Schowengerdt*, J. M. Iannelli, B. R. Hancock, J. K. Liu
Spring '89 MRS Meeting in April, 1989
*Colorado School of Mines, Golden, Colorado

"Time-Resolved RHEED Analysis of Growth Front Morphology and Initial MBE Film Nucleation of GaAs on Si (100) and (111) Surfaces."
F. J. Grunthaner, J. M. Iannelli, B. R. Hancock, J. K. Liu
Spring '89 MRS Meeting in April, 1989
"Interface Morphology and Growth Front Stoichiometry in InAs/GaAs Strained Layer Epitaxy"
F. J. Grunthaner, J. K. Liu, J. M. Iannelli, B. R. Hancock, F. D. Schowengerdt*
4th International Conference on Modulated and Metastable Semiconductors (MSS) in July 1989 in Ann Arbor, MI
*Colorado School of Mines, Golden, Colorado

"Interface Physics and Epitaxial Synthesis of Multilayer Materials"
F. J. Grunthaner

"RHEED as a Probe of Strained-Layer Synthesis and Crystallography"
F. J. Grunthaner
Invited presentation, Space Epitaxy Research Center Colliquium, University of Houston, Houston, Texas, January 26, 1989

"Critical Thickness and Dislocation Generation in InAs Strained-Layer Quantum Wells Grown on GaAs (100) Substrates"
F. J. Grunthaner, F. D. Schowengerdt, J. K. Liu, B. R. Hancock, J. M. Iannelli, P. Andersson
Physics of Compound Semiconductor Interfaces Conference (PCSI-16) Bozeman, Montana, February 7-10, 1989

"Stoichiometric Interface Control and Strained-Layer Epitaxy"
F. J. Grunthaner
Invited seminar, Distinguished Lecturer Series, Columbia University, NY, April 5, 1989

"III-V Strained-layer Synthesis and Novel Metastable Materials"
F. J. Grunthaner
Invited presentation, IBM T.J. Watson Research Center, Yorktown Heights, NY, April 6, 1989

"New Perspectives in Nanometer Control of Electronic Material Synthesis for Low-Dimensional Devices"
F. J. Grunthaner
Invited presentation, QUEST Colliquium on Future Device Opportunities, University of California at Santa Barbara, Santa Barbara, CA, August 26, 1989

Chemical And Electronic Structure of the SiO₂/Si Interface and the Electrically Active Defects"
F. J. Grunthaner, P. J. Grunthaner
Invited presentation, Third International Conference on Passivation, Hokkido University, Sapporo, Japan, September, 1989
Patents and New Technology Reports

"Hydrogen Stabilized Semiconductor Devices"
A.W. Overhauser, J. Maserjian
NASA Tech Brief NPO-17187 (patent pending)

"Oxidation of Semiconductors and Superconductors"
R. P. Vasquez
NASA Tech Brief NPO-17534 (patent pending)

"Variable-Energy Ion Beams for Modification of Surfaces"
A. Chutjian, M.H. Hecht, O.J. Orient
NASA Tech Brief NPO-17498

"Molecular Beam Epitaxy of CrSi₂ on Si (111)"
R.W. Fathauer, P.J. Grunthaner, T.L. Lin, D.N. Jamieson, J.H. Mazur
NASA Tech Brief NPO-17438

"Deposition of Pinhole-Free CoSi₂ Films"
T.L. Lin, R.W. Fathauer, P.J. Grunthaner
NASA Tech Brief NPO-17447
Electronic Device Technology

Publications

"New Flange Correction Formula Applied to Interfacial Resistance Measurements of Ohmic Contacts to GaAs"
U. Lieneweg, D.J. Hannaman

"Watt-Level Millimeter-Wave Monolithic Diode-Grid Frequency Multipliers"

"Oxidation of Silicon with a 5 eV 0− Beam"
M.H. Hecht, O.J. Orient, A. Chutjian, R.P. Vasquez

"Reactions of Fast Ground-State Oxygen Atoms with Surfaces"
O.J. Orient, A. Chutjian and E. Murad

"Barrier Height Enhancement of InP-Based n-Ga0.47In0.53As Schottky Barrier Diodes Grown by Molecular Beam Epitaxy"
J.H. Kim, S.S. Li, L. Figueroa

"PN Junction Properties of AlGaAs/GaAs Grown on GaAs-Coated Si Substrates by Liquid Phase Epitaxy"

Presentations

"B-I-N Diodes"
U. Lieneweg
Solid State THz Sources Workshop, Pasadena, CA, August, 1988

"Oxidation of Silicon with a 5 eV 0− Beam"
M.H. Hecht, O.J. Orient, A. Chutjian, R.P. Vasquez
19th IEEE Semiconductor Interface Specialists Conference, San Diego, December, 1988

"Interaction of Low-Energy O−(2P) and O(3P) Beams with a MgF2 Surface"
A. Chutjian, O.J. Orient, E. Murad
41st Annual Gaseous Electronics Conference, MN, October, 1988
"Experimental Investigations of Low-Energy (4-40 eV) Collisions of O(2P) and O(3P) Atoms with Surfaces"
A. Chutjian, O.J. Orient, E. Murad

"High Kinetic Energy vs. High Temperature: Studies in Reactions of Fast O Atoms"
A. Chutjian, O.J. Orient, E. Murad
Symposium on High Temperature and Materials Chemistry, Berkeley, CA, October, 1989

Patents and New Technology Reports

"Formula Gives Better Contact-Resistance Values"
U. Lieneweg, D.J. Hannaman
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"Tunable Submillimeter Wave Generator"
A.C. Gossard, J. Maserjian
NPO-17754

"Use of Variable-Energy Ion Beams for Surface Modification"
A. Chutjian, M.H. Hecht, O.J. Orient
NPO-17498 (patent pending)
Molecular Electronics

Publications

"Determination of Protein Orientation on Surfaces with X-ray Photoelectron Spectroscopy"
R. Margalit, R.P. Vasquez
J. Protein Chem. (in press)

"X-ray Photoelectron Spectroscopy Study of Surface Protein Orientation"
R. Margalit, R.P. Vasquez
Second International Conference of Molecular Electronics and Biocomputers, Moscow, USSR, September 11-18, 1989 (to be published by Kluwer Publishing, The Netherlands)

"Use of X-ray Photoelectron Spectroscopy in the Measurement of Protein Orientation on Surfaces"
R.P. Vasquez, R. Margalit
Thin Solid Films (submitted)

Presentations

"A Study of Protein Self-Assembly Using X-ray Photoelectron Spectroscopy"
R. Margalit and R. Vasquez

"Hemoproteins for Optical Processing Applications"
R. Margalit

"Metalloproteins Thin Films"
R. Margalit and R. Vasquez
Protein Society Meeting, Seattle, WA, July 29 - August 2, 1989

"X-ray Photoelectron Spectroscopy Study of Surface Protein Orientation"
R. Margalit, R.P. Vasquez
Second International Conference of Molecular Electronics and Biocomputers, Moscow, USSR, September 11-18, 1989

"Evidence for Oriented Protein Surface Layers using X-Ray Photoelectron Spectroscopy"
R. Margalit, R. P. Vasquez
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"Metalloprotein Thin Films"
R. Margalit, R. P. Vasquez
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"X-ray Photoelectron Spectroscopy Study of Hemoprotein Thin Films"
R. Margalit, R. P. Vasquez
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"Indicator for Pseudomonas Bacteria"
R. Margalit
NASA Tech Brief NPO-17653
Overview

This section concentrates on optoelectronic materials and devices. Optical processing is included in the section on Computer Architecture and Subsystems. Optoelectronic devices, which generate, detect, modulate, or switch electromagnetic radiation are being developed for a variety of space applications. The program includes spatial light modulators, solid state lasers, optoelectronic integrated circuits, infrared detectors, photovoltaic devices, nonlinear optical materials and devices, and fiber optics.

1988-1989 Major Technical Achievements

Spatial Light Modulators

- **Demonstrated** two different photo-optic effects based on combining nipi and multiple quantum well structures grown by MBE. Results indicate that high-performance, optically addressed, spatial light modulators (O-SLM's) can be achieved using these effects in appropriate structures.

Lasers

- **Fabricated** InGaAsSb/AlGaAsSb lasers capable of room temperature operation at 2.1 μm. This wavelength capability is important for LIDAR observations of planetary atmospheres.

- **Demonstrated** the monolithic integration of second-order, e-beam-written gratings with AlGaAs/GaAs lasers. The gratings serve as spatially selective filters to substantially reduce near and far-field emission widths from broad-area lasers. Such improvement of the coherence of broad-area lasers is important for high-power applications. The work was done in a collaboration with the National Nanofabrication Laboratory of Cornell University where the e-beam writing was performed.

- **Demonstrated** double heterostructure (DH) AlGaAs/GaAs stripe-geometry lasers on Si substrates with world-record performance. The DH stripe lasers exhibited the highest peak power (184 mW/facet) on record for this heteroepitaxial system. These laser structures were prepared by hybrid growth of migration-enhanced molecular beam epitaxy (MEMBE) followed by MOCVD.

- **Demonstrated** graded-index separate-confinement heterostructure (GRINSCH) AlGaAs/GaAs single quantum-well lasers on Si by migration enhanced molecular beam epitaxy (MEMBE) followed by MOCVD in collaboration with Hughes Research Lab. These lasers exhibited the highest peak power (450 mW/facet) on record for low-threshold-current quantum-well lasers in this important heteroepitaxial system.
Fabricated high-quality pseudomorphic InGaAs/AlGaAs single quantum well lasers on GaAs substrates. These lasers have state-of-the-art threshold currents, and the observed quantum efficiency and output power represent world records for this materials system.

**Optoelectronic Materials and Characterization**

- Developed a laboratory electron beam lithography system based on a scanning electron microscope.
- Developed a low temperature cathodoluminescence system based on a novel optical fiber light collection system. The U.S. patent on this system has been issued.
- Fabricated quantum wires in the GaAs (AlGaAs) system by diffusion induced disordering.
- Developed a novel cathodoluminescence based technique for measurement of electronic diffusion lengths.
- Developed a new multiband formalism for analysis of band structure and optical matrix elements in quantum dot and quantum wire structures.
- Invented several new paramagnetic organic molecules and established their spectroscopy and chemical reactivity patterns.
- Established a new mechanism for ferromagnetic coupling of electron spins in organic materials; such interactions are critical to the design of magnetic materials.
- Invented a new class of organic polymers that can be doped to produce a large number of spins; preliminary measurements (SQUID) indicate significant, cooperative magnetic behaviors.

**Optoelectronic Integrated Circuits**

- Fabricated the first 10x10 array of neuron devices for neural network applications as part of a JPL/Caltech collaboration. The integrated device contains a detector, LED emitter and an amplifier at each pixel.

**Infrared Detectors**

- Demonstrated the reproducibility of Germanium Blocked Impurity Band (GeBIB) devices for far infrared wavelengths. Initial measured performance demonstrates response to beyond 200 microns, 4.5 A/W at 102 microns, and a dark current of less than 1000 e/s. This effort is being conducted at JPL, Caltech, University of Rochester and the Rockwell Science Center in Anaheim, California.
Developed a novel MBE process capable of growing single-crystal columns of CoSi$_2$ embedded in a Si matrix. This process enables the fabrication of a new Schottky-like IR detector with augmented quantum efficiency, "the layered internal photoemission sensor" (LIPS).

Fabricated InAs PIN photodiodes in collaboration with Cincinnati Electronics showing 75% quantum efficiency at 77 K, with cutoff wavelengths of 2.8-3.0 μm, and with an areal yield of better than 85%. The quantum efficiency measurements were made with illumination through the GaAs substrate.

Fabricated InAs tunnel diodes by MBE on GaAs substrates with 14:1 peak to valley ratio. This result demonstrates the ability to achieve high doping p$^+$n$^+$ InAs diodes with high quality on GaAs. It is also a precursor result for fabricating InAs doping superlattices for LWIR detectors.

Fabricated IrSi/Si p-type Schottky-diode detectors using MBE, which permits the growth of uniform, single-phase silicide layers. These detectors exhibit infrared photoresponse out to 8 μm, and offer the potential of extended-range focal-plane arrays compatible with Si-based technology.

Extended the range of infrared response of CoSi$_2$ Schottky diodes by the use of MBE doping technology, which permits the precise placement of high-density doping layers adjacent to the metal-semiconductor interface. This technology may be applied to other silicide IR sensors as well.

Nonlinear Optical Materials and Characterization

Synthesized new organic and organometallic materials with very large second order optical nonlinearities exhibiting powder second harmonic generation efficiencies 2000X that of urea, the industry standard; demonstrated the feasibility of using these materials in thin film electro-optic modulators.

Synthesized new processable polymers with large nonresonant third-order nonlinear optical susceptibilities having very low optical losses (1000X less than polyacetylene), a critical feature for photonic applications.

Demonstrated optical limiters for laser eye protection based on silicon containing naphthalocyanine dyes. These materials are normally transparent in the visible spectrum, but limit throughput of high intensity optical radiation to a few microjoules or less depending on the pulse duration.

Developed theoretical and experimental strategies for designing molecular level optical, electronic or photonic devices based on electron transfer.

Achieved net gain coefficients for beam coupling in photorefractive GaAs of up to 140% using four-wave mixing. These results illustrate the potential for development of cascadable optical processors using photorefractive GaAs.

Demonstrated interaction of mutually incoherent light beams in photorefractive GaAs crystals, illustrating the potential of optical processing using incoherent light beams of different wavelengths in semiconductors.
Fiber Optics

- Developed concept of real-time interface for 100 mbit FDDI network. Will allow free mixing of voice, video, and data on fiber optic token ring network.

Photovoltaic Technology

- Demonstrated for the first time the growth of diamond-like carbon thin films by electron cyclotron resonance plasma deposition. The technology has application to high temperature devices and to advanced optical coatings for sensor protection in space.
Spatial Light Modulators

Publications

"An Optically Controlled Absorption Modulator Based on State Filling of In_x Ga_{1-x} As/GaAs Quantum Wells"
J.M. Iannelli, J. Maserjian, B.R. Hancock, P.O. Andersson, F.J. Grunthaner

"An Optically Controlled Reflection Modulator using GaAs/AlGaAs nipi/Multiple Quantum Well Structures"

Presentations

"Spatial Light Modulation in GaAs"
L.J. Cheng, G. Gheen, and D.T.H. Liu

"On the Progress of the Liquid Crystal Television Spatial Light Modulator"
T.H. Chao, H.K Liu

"Optically Addressed Spatial Light Modulators by MBE Grown nipi/MQW Structures"
J. Maserjian, P.O. Andersson, B.R. Hancock, J.M. Iannelli, S.T. Eng, F.J. Grunthaner
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L.J. Cheng, G.O. Gheen, A. Partovi
NASA Tech Brief NPO-17228

"Photodiode-Coupled Multiple Quantum Well Modulator"
J. Maserjian, S.T. Eng
NASA Tech Brief NPO-16298

"Monolithic III-V/Silicon Modulator"
J. Maserjian, S.T. Eng
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"Photovoltaic-Driven Strain-Layer-Superlattice Modulator"
J. Maserjian
NASA Tech Brief NPO-16915 (patent pending)
"Photovoltaic-Driven Quantum Well Modulator"
J. Maserjian
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"Electroabsorption Monolithic Modular Array"
J. Katz, et. al.
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"Improvements on Photovoltaic-Driven Multiple Quantum Well Modulator"
J. Maserjian
NPO-17357 (patent pending)

"Multiple Quantum Well Optical Modulator"
J. Maserjian
CIT 1881-A, U. S. Patent No. 4,818,079

"All Optical Photochromic Spatial Light Modulators"
D. N. Beratan, J. W. Perry
NASA Tech Brief NPO-17612
Lasers

Publications

"High-Power Low-Threshold Graded-Index Separate Confinement Heterostructure AIGaAs Single Quantum Well Lasers on Si Substrates"
J.H. Kim, R.J. Lang, G. Radhakrishnan, J. Katz, A. Narayanan, R.R. Craig

"High-Power AlGaAs/GaAs DH Stripe Lasers on GaAs-on-Si Prepared by Migration-Enhanced Molecular Beam Epitaxy"
J.H. Kim, G. Radhakrishnan, A. Nouhi, J.K. Liu, J. Katz

"Narrow Far Fields from Extended-Window Broad Area Lasers"
R.J. Lang, S. Forouhar, J. Cser, J. Katz, P. Gavrilovic, J. Williams, W. Stutius, A. Chin

"Measurement of a Relaxation Resonance, Damping and Nonlinear Gain from Sidebands in the Field Spectrum of a 1.3 µm InGaAs DFB Laser"
R.J. Lang, H.P. Mayer, W. Elsasser, H. Schweizer, A.P. Mozer

"Modulation Bandwidth of GaAs/AlGaAs Single Quantum Well Lasers Operating at the Second Quantized State"
A. Larsson and L. Lindstrom

"Highly Coherent Long Cavity GaAs/AlGaAs Single Quantum Well Lasers"
A. Larsson, P.A. Andrekson, B. Johnson, L. Lindstrom

"High Speed Ga0.47In0.53As/InP Infrared Schottky Barrier Photodiodes"
J.H. Kim, S.S. Li, L. Figueroa, T.F. Carruthers, R.S. Wagner

"High-Speed InP-Based InxGa1-xAs Schottky Barrier Infrared Photodiodes for Fiber-Optic Communications"
J.H. Kim, S.S. Li, L. Figueroa, T.F. Carruthers, R.S. Wagner

"High Peak Power Low Threshold AlGaAs/GaAs Stripe Layer Diode on GaAs-on-Si by Hybrid Migration-enhanced MBE and MOCVD Growth"
J. H. Kim, A. Nouhi, G. Radhakrishnan, R. J. Lang, J. Katz

"Al0.3Ga0.7As/Al0.05Ga0.95As Light-Emitting diodes on GaAs-Coated Si Substrates Grown by Liquid Phase Epitaxy"
S. Sakai, S.S. Chang, R.V. Ramaswamy, J.H. Kim, G. Radhakrishnan, J. Katz
"Narrow Far Fields From Extended-Window Broad Area Lasers"
R. J. Lang, S. Forouhar, J. Cser, J. Katz, P. Gavrilovic, J. Williams, W. Stutius, A. Chin

"An Exact Formulation of Coupled-Mode Theory for Coupled-Cavity Lasers"
R. J. Lang, A. Yariv

"High-Power AlGaAs/GaAs DH Stripe Laser Diodes on GaAs-on-Si Prepared by Migration-enhanced Molecular Beam Epitaxy"
J. H. Kim, G. Radhakrishnan, A. Nouhi, J. K. Liu, R. J. Lang, J. Katz

"Measurement of Relaxation Resonance, Damping and Nonlinear Gain From Sidebands in the Field Spectrum of a 1.3 mm InGaAsP DFB Laser"

"A High-Speed In-Based InGaAs Schottky Barrier Infrared Photodiode for Fiber-Optic Communications"
J.H. Kim, S.S. Li, L. Figueroa, T.F. Carruthers
Proceedings of the IEEE Electronic Devices and Materials Symposium, Taiwan, August 29-31, 1988, p. 192

"High-Peak-Power Low-Threshold AlGaAs/GaAs Strip Laser Diodes on Si Substrates by Hybrid MBE and MOCVD Growth"
J.H. Kim, A. Nouhi, G. Radhakrishnan, J. Katz

"High-Power AlGaAs/GaAs Stripe Laser Diode on GaAs-on-Si Substrates Grown by Migration-Enhanced Molecular Beam Epitaxy"
J.H. Kim, A. Nouhi, G. Radhakrishnan, R.J. Lang, J. Katz

Presentations

"GaInAsSb/AlGaAsSb Injection Lasers for Remote Sensing Applications"
S. Forouhar, J. Cody, J. Katz
SPIE Vol. 1062, 16 (1989)

"GaAs/AlGaAs Corner Reflector Laser for Monolithic Integration"
M. Hagberg, A. Larsson, S.T. Eng
15th European Conference on Optical Communication, Gothenburg, Sweden, September 10-14, 1989
"High-Power Low-Threshold Graded-Index Separate-Confinement Single Quantum Well Lasers on Si Substrates Prepared by Migration-Enhanced Molecular Beam Epitaxy"
J.H. Kim, R.J. Lang, G. Radhakrishnan, J. Katz, A. Narayanan, R.R. Craig
IEEE LEOS '89 Annual Conference, Orlando, FL, October, 15-20, 1989

"Spectral and Dynamic Properties of GaAs/AlGaAs Single Quantum Well Lasers"
A. Larson, P.A. Andrekson, B. Jonsson, L. Linstrom
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"Separated Large Optical Cavity GaAs/AlAs Diode Lasers"
S.J. Lee, R.V. Ramaswamy, P.S. Zory, L. Figueroa, J.H. Kim
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"Diffraction-Coupled-Output Lasers for High Optical Powers"
S. Forouhar, R.J. Lang, J. Cser, J. Katz

"Semiconductor Laser Technology for Remote Sensing Experiments"
J. Katz
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J.H. Kim, A. Nouhi, G. Radhakrishnan, R.J. Lang, J. Katz
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"A High-Speed InP-Based InGaAs Schottky Barrier Infrared Photodiode for Fiber-Optic Communications"
J.H. Kim, S.S. Li, L. Figueroa, T.F. Carruthers
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J. W. Perry, A. H. Zewail, T. Cole
NPO-17916

"Multiperiod Grating Surface-Emitting Laser"
R.J. Lang
NPO-18054

"Surface Emitting Laser with Integrated Multilayer Reflector"
R.J. Lang
NPO-17763 (patent pending)

"High-Power AlGaAs/GaAs Single Quantum Well Lasers on Migration-Enhanced Molecular Beam Epitaxial GaAs-Coated Si Substrates"
J.H. Kim, R.J. Lang, G. Radhakrishnan, J. Katz
NPO-17988
"Annular Bragg Grating Surface Emitting Laser"
R.J. Lang
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"Unstable Resonator DBR Laser"
R.J. Lang
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Optoelectronic Materials and Characterization

Publications

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T.E. Batchman, R.F. Carson, R.L. Gallawa, H.J. Wojtunik, Editors

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S. Borenstain, J. Katz

"Cathodoluminescence System for a Scanning Electron Microscope Using a Novel Optical Fiber Light Collection System"
M. Hoenk, K.J. Vahala

"Nanometer Scale Wire Structures Fabricated by Diffusion Induced Disordering of a GaAs (AlGaAs) Quantum Well"
H.A. Zarem, P.C. Sercel, M.E. Hoenk, J.A. Legens, K.J. Vahala

"Direct Determination of the Ambipolar Diffusion Length in GaAs/AlGaAs Heterostructures by Cathodoluminescence"
H.A. Zarem, P.C. Sercel, J.A. Lebens, L.E. Eng, A. Yariv, K.J. Vahala

"Effect of Aluminum Mole Fraction on Carrier Diffusion Lengths and Lifetimes in AlGaAs"

"Multiband Envelope Theory in a Spherical Representation: Application of a Super-J Basis to Centrosymmetric Semiconductor Heterostructures"
K.J. Vahala, P.C. Sercel
Phys. Rev. Lett. (submitted)

"Quantum Wires and Quantum Dots: Physics and Applications"
K.J. Vahala

"Disorder of a GaAs-AlGaAs Quantum Well as a Technique for Fabricating Quantum Wires"
H.A. Zarem, P.C. Sercel, M. Hoenk, A. Yariv, K.J. Vahala
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"Nanometer Scale Bandgap Modulation by Disorder of a GaAs-AlGaAs Quantum Well"
H.A. Zarem, P.C. Sercel, M. Hoenk, A. Yariv, K.J. Vahala
"Quantum Wire and Quantum Dot Lasers"
K.J. Vahala

"Quantum Wire and Quantum Dots in Semiconductor Lasers"
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"Quantum Wire and Quantum Dot Semiconductor Lasers: Physics and Fabrication"
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"Quantum Confinement for Optoelectronic Devices: Beyond the Conventional Quantum Well"
K.J. Vahala

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P.C. Sercel, H. Zarem, J. Legens, L. Eng, A. Yariv, K.J. Vahala

"Cyclobutanediyls: A New Class of Localized Biradicals. Synthesis and EPR Spectroscopy"
R. Jain, M.B. Sponsler, F.D. Coms, D.A. Dougherty
J. Am. Chem. Soc. 110, 1988, 1356

"1,3-Diphenyl-1,3-cyclopentanediyl: A Remarkably Stable Localized Biradical"
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M.B. Sponsler, R. Jain, F.D. Coms, D.A. Dougherty

"Diphenylbicyclo[2.1.0]pentane. A Persistent Hydrocarbon with a Very Weak C-C Bond"
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"Quantum Wires and Quantum Dots: Physics and Applications"
K.J. Vahala

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H.A. Zarem, P.C. Sercel, M. Hoenk, A. Yariv, K.J. Vahala

"Quantum Wire and Quantum Dot Lasers"
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"A Novel Technique for the Direct Determination of Carrier Diffusion Lengths in GaAs/GiGaAs Heterostructures Using Cathodoluminescence"
P.C. Sercel, H. Zarem, J. Legens, L. Eng, A. Yariv, K.J. Vahala
Optoelectronic Integrated Circuits

Publications

"Monolithically Integrated Two-Dimensional Arrays of Optoelectronic Threshold Devices for Neural Network Applications"
J.H. Kim, S.H. Lin, J. Katz, D. Psaltis

"Integration of High-Gain Double Heterojunction of GaAs Bipolar Transistors with a LED for Optical Neural Network Applications"
S.H. Lin, J.H. Kim, J. Katz, D. Psaltis

"System Issues Relating to Laser Diode Requirements for VLSI Holographic Optical Interconnects"
E. Bradley, P.K.L. Yu, A.R. Johnston

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"Monolithically Integrated Two-Dimensional Arrays of Optoelectronic Threshold Devices for Neural Network Applications"
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"Optimum Design of High-Gain AlGaAs/GaAs Double Heterojunction Bipolar Transistors for Optoelectronic Integrated Circuit Applications"
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Patents and New Technology Reports

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D. Psaltis, J. Katz, J.H. Kim, S.H. Lin
NASA Tech Brief NPO-17652

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J.H. Kim, S.H. Lin
NPO-18101
Infrared Detectors

Publications

"Infrared Pre-Detection Dynamic Range Compression via Photorefractive Crystals"
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"Tunable Quantum Well Infrared Detector"
K.L. Doughty, P.O. Holtz, R.J. Simes, A.C. Gossard, J.L. Merz, J. Maserjian
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"Tunable Quantum Well Infrared Detector"
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R.W. Fathauer, T.L. Lin, J.M. Iannelli, P.J., Grunthaner, J. Maserjian
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J. Maserjian
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"Silicon-Compatible Infrared Sensors"
P. J. Grunthaner
AVS Thin Film and Surface Science Open House, Jet Propulsion Laboratory, California Institute of Technology, Pasadena, CA, January 23, 1989

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T.N. Krabach, J.E. Huffmann, D.M. Watson
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Overview

Advanced concepts in hardware, software and algorithms are being pursued for application in next generation space computers and for ground-based analysis of space data. The research program focuses on massively parallel computation, neural networks, and optical processing. Also included are small seed efforts in novel magnetic memories and molecular computation. A common theme is fault tolerance which is required for space applications and for acceptable mean time to failure in massively parallel ground computers.

1988-1989 Major Technical Achievements

Parallel Computation

- The Hypercube Project completed its third generation objective when, in April, the 128-node Mark IIIIfp was assembled and verified. Many of the 200-plus science and engineering applications that had been run on smaller hypercubes were extended on the large machine, and system timing tests showed that it operated as one of the most powerful supercomputers in the world today. One Caltech physics problem in quantum chromodynamics was computed at a rate of over 700 million floating point operations per second.

- Demonstrated Hyperswitch Adaptive Message Routing VLSI chip with a data throughput per channel of 400 Mbits/s and adaptive network reconfiguration for a number of random channel failures. The above tests were verified with a laboratory testbed configuration.

- Collaborated on the system development and evaluation of the Hyperswitch Communication Network (HCN) with a large computer company. This multiprocessor computer will result in a machine ready for mission critical large-scale applications.

- Developed simulation methods key to complex distributed systems modeling and performance evaluation. This work has the support of the above HCN collaboration.

- Developed a conceptual design for a fault-tolerant hypercube which can be implemented as a ground-based hypercube or be used as the basis for a flight hypercube.

- Developed and demonstrated a Concurrent Image Processing Executive for the SUN/hypercube high-performance workstation environment.

- During the Voyager Neptune encounter period in August the JPL Image Analysis Systems Group employed an 8-node Mark IIIIfp hypercube to process the images that were used to create the mosaics and rotational movies that were essential to displaying and understanding the atmospheric dynamics of the planet in near real time. The computational requirements are large; they include photometric correction, corrections for spacecraft navigation and pointing parameters, geometric projections to be used for map registration, creation of mosaics, and analysis of the motions of features in the imagery. Their 8-node machine operated at 60 to 80 times the speed of the computer system used conventionally for these computations, a VAX 8600.
Four electromagnetic (EM) scattering and radiation analysis programs have been developed for the hypercube. These programs are being used to design and analyze metallic structures such as the Global Positioning System Rogue Receiver choke ring antenna. A major emphasis of this EM research effort is developing analysis tools which are particularly suited to a parallel environment such as the finite element parallel partitioning and load balancing algorithms, and the efficient parallel sparse and dense matrix solvers.

Other applications that have been developed include a 2-d electrostatic particle-in-cell plasma simulation, synthetic aperture radar data analysis, radiative transfer calculations for atmospheric parameter retrieval, image processing of multi-spectral data, vortex flow analysis, crustal deformation studies, and complex simulations. These applications typically run with an efficiency of 80 to 95 percent. That means that a program using a 32-node hypercube will run 26 to 30 times faster than one on a single node without accruing substantial penalty for message passing or node synchronization.

The hypercube is now being employed to run large distributed simulations of multi-processor computer systems as a design and analysis tool for future generations of such machines. The Hypercube Project is simulating their next generation communications processor using the Time Warp operating system that has been under development by JPL and UCLA for several years. The implementation allows distributed discrete-event simulations of machines of up to 2048 processing nodes under varying workloads and communication requirements to be run extremely quickly compared to simulations that can be run only on traditional sequential machines.

Demonstrated 4-node MAX multicomputer designed for general purpose, fault-tolerant spacecraft applications. This effort will result in a flight qualifiable, low power, low mass parallel processor suitable for a wide range of missions.

Demonstrated new dataflow software design methodologies for MAX multicomputers that simplify development of flight software.

Developing flight qualifiable designs for two custom VLSI chips supporting the MAX multicomputer.

Developing a custom VLSI chip (300,000 transistors) and overall system for the Human Genome Project. This biological system will have the performance of over 40 Cray-2 supercomputers at 1/1,000 of the cost.

Neural and Analog Computing

Demonstrated a floating gate field effect transistor with analog memory in VLSI, for the first time using double-poly process (MOSIS), a strong contender as a synapse for electronic neural networks with on-chip learning capability.

Designed and fabricated a wide spectrum of cascadable, programmable, CMOS/VLSI synaptic chips with binary to 11-bit resolution, as well as multineuron chips. This has led to transfer of neural nets hardware technology to U.S. industries.
- Developed "building blocks" for high speed image processing/pattern recognition applications. The building blocks consist of:
  - A fabricated 62x62 thin film, binary, nonvolatile, programmable, high density synaptic array with a nominal feature size of 2 microns based on amorphous chromium silicon alloy system.
  - A designed and fabricated 64-neuron CMOS/VLSI "winner-take-all" cascadable chip with a winner lockout feature. It selects the best pattern match in less than 10 microseconds (with an effective search rate of more than $10^9$ bits/sec for a 64-bit x1000 word memory).

- Developed a unique, versatile neurocircuit simulator, a valuable neural net hardware design aid, which takes the realistic hardware component characteristics into account during simulation, for a variety of neural net architectures and algorithms.

- Demonstrated, for the first time, Euclidean distance minimization in fully parallel hardware for multidimensional vector quantization. It has been successfully applied to terrain trafficability determination with a 10 to 100 times speed improvement over digital computing approach. This has paved the way for rapid hardware prototyping of several selected neuroprocessors for DoD applications.

- Made a major algorithmic/architectural breakthrough allowing a novel neural nets approach to computationally intensive problems of combinatorial optimization (e.g., the famous Traveling Salesman Problem, TSP) using our unique "analog prompting scheme." This has resulted in:
  - A software as well as a hardware demonstration of the TSP solutions using the hybrid neuro-computer and the VLSI based neural net system.
  - Implementation of a consumer-resource assignment problem, demonstrating for the first time the multiple assignment solution in hardware with a phenomenal speed of a few microseconds.

- Demonstrated for the first time, by circuit simulation, that a novel design of our analog resource allocation chip solves a one-to-one assignment problem of 32 tracks to 32 targets (with a search space of over $10^{35}$ possible solutions) in ~100 microseconds, a 4-orders of magnitude faster response than even an 8-node Mark III hypercube machine.

- Demonstrated the high speed performance of a "trained" neuro-processor hardware interfaced with an experimental robotic arm for positioning the end-effector of the arm within the selected work space. The network is trained under supervision with an error-back-propagation algorithm, and executes the inverse kinematics transformation in less than 10 microseconds.
Neural and Nonlinear Theory

- **Implemented** image enhancement filters and reading rate software on a Sun workstation which was enhanced using high-speed digital hardware to develop a clinical prototype for improving the reading performance of low vision observers using commercially available closed circuit television.

- **Designed and implemented** fast accurate dynamic image analysis of natural scenes based on biological models using a layered neural network to reconstruct the depth map that analyzes the scene across several sensory dimensions, such as texture, position, motion parallax, shape from shading, illumination, and occlusion. Implemented feedforward and feedback connections using nonlinear adaptive thresholding, region growing, changes in optical flow, and Hebbian learning to improve 3D reconstruction.

- **Designed** a dynamic imaging system (based on layered biological neural networks and image enhancement to improve resolution of objects) to be used for mapping out the surfaces of unknown terrain (e.g., planetary imaging, and navigating robotic vehicles close to real-time frame rates).

- **Discovered** a new type of attractor in nonlinear dynamical systems: this attractor, named "Terminal Attractor" ensures infinite local stability of information encoded in neural networks and enables suppression of spurious states in associative memories.

- **Developed** a radically new method for supervised learning using neural networks with non-lipschitzian dynamics. Dramatic increase in the speed of learning (over state-of-the-art back-propagation algorithms) has been achieved, and the methodology enables systematic incorporation of event-driven constraints in real-time.

- **Developed** a new formalism for unsupervised learning from examples presented to a neural network. Each example is considered as an "interpolation node" of the networks velocity field in phase space, thereby enabling automatic clustering for pattern recognition.

- **Discovered** a fundamentally new class of nonlinear dynamical systems: the unpredictable systems with creative dynamics. Such systems are presented in the form of coupled activation and learning dynamical equations whose ability to be spontaneously activated is based upon two pathological characteristics. Firstly, such systems have zero Jacobian. As a result of that, they have an infinite number of equilibrium points which occupy curves, surfaces of hypersurfaces. Secondly, all these equilibrium points become terminal attractors or repellers depending upon the sign of the periodic excitation. Potential applications may range from encryption to machine intelligence.

- **Demonstrated** fast learning algorithms based on adjoint operator theory. The development of learning algorithms is generally based upon the minimization of a "neuromorphic" energy-like function. A fundamental requirement of all currently available approaches is the computation of the gradient of this objective function with respect to the various parameters of the neural architecture such as synaptic weights, neural gains, decay constants, etc. In principle, the computation requires the solution of a system of nonlinear equations for each parameter of the network. Our new methodology enables us to gather all the information required to compute...
the energy gradients with respect to all network parameters by solving a single set of (linear) adjoint equations. The information so obtained can also be used to propagate architecture uncertainties (expressed as covariance matrices) to a network response of interest.

- **Discovered** the existence of chaotic oscillations in massively parallel neural networks and developed a new methodology enabling correct recovery of information under concurrently asynchronous operating regimes. The methodology constitutes the first demonstration of true fault-tolerance capabilities in neural networks.

- **Developed** a biologically inspired computational methodology for hyperacute global sensory resolution from a pool of potentially coarse or unreliable single receptors.

- **Demonstrated** that oscillations can serve as local distributed clocks in analog calculations and can encode and label temporal information by several phase and frequency adjusting mechanisms. The methodology is expected to become a cornerstone for applications such as signal pattern search, sequence likelihood estimation and signal presence indication.

- **Developed** smart retina neural network architecture that generates translation and rotation invariant representations of star maps for the JPL neural network star pattern identifier.

- **Completed** the computer simulation for the comparison of the inner- and outer-product algorithms of the Hopfield-type neural net with difference binary data representations. Discovered a unified approach for input data representation.

- **Discovered** the application of the new terminal attractor binary associative (TABAM) neural processing for the reduction or elimination of spurious states. Derived a model for binary data representation for optical implementation and conceived optical architectures for the new model.

- **Demonstrated** the inner-product neural network using a diffuser, a Hughes LCLVSLM, and the LCTVSLM originally developed at JPL.

**Optical Processing**

- **Demonstrated** a shortest Hamming distance based optical associative memory breadboard.

  - Suitable for both auto- and hetero-associative recall.

  - Suitable for accurate similarity measure between images.

  - Suitable for radar image processing.
Developed an innovative optical associative memory architecture using opto-electronic light amplifiers.

- Can be miniaturized.
- Can be cascaded to multiple layers.

Demonstrated matrix-vector and vector-vector multiplications with large arrays of elements, optical correlation, image substraction, and logic operations using photorefractive GaAs.

Demonstrated spectral imaging of an outdoor scene using an imaging spectrometer breadboard with an acousto-optic tunable filter of TeO2.

Demonstrated the feasibility of using GaAs crystals as interaction media for high-speed image correlation and convolution applications.

Achieved matrix-vector operations using four-wave mixing in photorefractive compound semiconductors.

Demonstrated an optical pseudocolor encoding method to enhance visibility of interesting features of an image using colors representing different signal densities and object brightness.

Achieved auto- and hetero-associative memory using a two-dimensional optical logic gate.

Demonstrated for the first time phase conjugate interferometers using photorefractive GaAs, which have potentials to be utilized in high-speed optical computing, novelty filters, and moving target tracking.

Established the feasibility of using photorefractive GaAs as a real-time dynamic volume holographic medium for optical and image processing applications.

Data Storage

Designed complete VLSI memory chips (with I/O) using Vertical Bloch Line (VBL) pairs as memory elements, for use with nonvolatile, radiation hard magnetic garnet technology. Fabrication is proceeding under contract on devices with 10 Mbit/cm² and 25 Mbit/cm² densities. Test chips have been designed and fabricated (and are undergoing testing) for evaluating operation of the storage cells (i.e. minor loops). Magnetostatic performance simulations were conducted for a VBL output detector and major line gates (i.e. output gates).

Invented a magnetic-Hall effect random access memory which offers densities greater than SRAM, sub-100 nanosecond access time, nonvolatility, low power consumption, and SEU and radiation hardness.

Simulated performance of Hall sensors in the magnetic-Hall effect random access memory, accounting for certain fabrication variations and domain variations in the magnetic layer. Measurements of large-scale InSb Hall sensors were made for comparison.
• Established a new data storage laboratory with magnetic and magneto-optical effect test equipment.

Molecular Computation

• There has been much activity, both theoretical and experimental in the area of strategies for designing molecular level optical, electronic or photonic devices based on electron transfer. The molecular shift register memory concept developed last year has been generalized to yield a number of device architectures. In addition, experiments have been under way to measure rates and quantum yields of single and two step intramolecular electron transfer reactions as a function of chemical structure and environment.
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"Optical Pseudocolor Image Enhancement with Real-Time Large Screen Display"
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"Matrix-Vector Multiplication in Thin Photorefractive Semiconductor Crystals"
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L. J. Cheng
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"Computer Simulation of Gates for Ion-Implanted Devices"
M. Alex, J.C. Wu, M.H. Kryder

"Computer Simulated Model of Thermomagnetic Writing"
R. Weng, J.C. Wu, Z.J. Cendes, M.H. Kryder

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"Vertical Bloch Line Memory"
H. L. Stadler
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R. R. Katti
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R. R. Katti and H. L. Stadler

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R. R. Katti
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H. L. Stadler
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"Computer Simulation of Gates for Ion-Implanted Devices"
M. Alex, J.C. Wu, M.H. Kryder

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J. C. Wu, H. L. Stadler, R. R. Katti
NPO-17954

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R. R. Katti
NPO-17998

"Photochromic Recording Process and Media"
R. R. Katti, D. Coulter
NPO-18010
Molecular Computation

Publications

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D.N. Beratan, J.J Hopfield, J.N. Onuchic

"Information Storage at the Molecular Level: the Design of a Molecular Shift Register Memory"
D. N. Beratan, J. N. Onuchic, J. J. Hopfield

"The Influence of Gap States on the Non-Resonant Second Hyperpolarizabilities of Conjugated Organic Polymers"
D.N. Beratan

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D. N. Beratan
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"Molecular Implementation of a Molecular Shift Register Based on Electron Transfer"
J. N. Onuchic, D. N. Beratan
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"Molecules with Enhanced Electronic Polarizabilities Based on 'Defect'-Like States in Conjugated Polymers"
D.N. Beratan
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D.N. Beratan, J.W. Perry
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Overview

The goals of this program are to develop custom microcircuit technology, also known as Application Specific Integrated Circuits (ASICs) technology, for use in flight and ground programs. Supporting this effort are activities to investigate the effects of the space environment, and particularly ionizing radiation, on microcircuits and to develop a space qualification methodology. Another aspect of the program emphasizes innovative applications of custom microcircuit technology to image and signal processing and communications.

1988-1989 Major Technical Achievements

Application Specific Integrated Circuits

- **Fabricated** Direct Memory Access Coprocessor through MOSIS for system testing. First silicon received in August 1989, tested and found to be 100% functional. System testing on the Mariner Mark II spacecraft breadboard computer is underway.

- **Designed and submitted** for fabrication a Silicon Controller chip which will control 21 gallium arsenide phase shifter chips in a 2-dimensional, 21-element phased array antenna system.

- **Demonstrated** a floating gate field effect transistor with analog memory in VLSI using double-poly process (MOSIS), a strong contender as a synapse for electronic neural networks with on-chip learning capability.

- **Designed and fabricated** a wide spectrum of cascadable, programmable, CMOS/VLSI synaptic chips with binary to 11-bit resolution, as well as multi-neuron chips. This has led to transfer of neural net hardware technology to U.S. industries.

- **Developed** "building blocks" for high speed image processing and pattern recognition applications. The building blocks consist of:
  - A **fabricated** 62x62 thin film, binary, nonvolatile, programmable, high density synaptic array with a nominal feature size of 2 microns based on amorphous chromium silicon alloy system.
  - A **designed and fabricated** 64-neuron CMOS/VLSI "winner-take-all" cascadable chip with a winner lockout feature. It selects the best pattern match in less than 10 microseconds (with an effective search rate of more than $10^9$ bits/sec for a 64-bit x1000 word memory).

- **Fabricated and successfully tested** player-detector chip for Army-funded Simulation of Area Weapons Effects (SAWE) program.

- **Developed** VLSI design of a universal noiseless coder for the Image Spectrometer of Flight Processor (ISFLIP).

- **Developed** VLSI design of systolic tree-search vector quantizer for Eos on-board SAR processor.
• Designed two versions of a custom chip for the Big Viterbi Decoder (BVD) and the Deep Space Network (DSN):
  - A standard cell device, produced through United Technologies Microelectronics Center (UTMC)
  - A gate array device, produced through VLSI Technology Inc. (VTI)

• Developing flight qualifiable designs for two custom VLSI chips supporting the MAX multicomputer.

• Demonstrated Hyperswitch Adaptive Message Routing VLSI chip with a data throughput per channel of 400 Mbits/s and adaptive network reconfiguration for a number of random channel failures. The above tests were verified with a laboratory testbed configuration.

• Developing a custom VLSI chip (300,000 transistors) and overall system for the Human Genome Project. This biological system will have the performance of over 40 Cray-2 supercomputers at 1/1,000 of the cost.

• Designed complete VLSI memory chips (with I/O) using Vertical Bloch Line (VBL) pairs as memory elements, for use with nonvolatile, radiation hard magnetic garnet technology. Fabrication is proceeding under contract on devices with 10 Mbit/cm² and 25 Mbit/cm² densities. Test chips have been designed and fabricated (and are undergoing testing) for evaluating operation of the storage cells (i.e., minor loops). Magnetostatic performance simulations were conducted for VBL output detector and major line gates (i.e., output gates).

Quality Assurance and Space Qualification Methodology

• Designed and tested 4k CMOS SRAM to characterize SEU susceptibility of CMOS process. Performed SEU testing at Berkeley 88-inch cyclotron. Demonstrated that the LET upset threshold can be adjusted via external offset voltage to allow bench-level SEU testing using an alpha particle source.

• Developed new technique for determining and controlling temperature in multi-segment interconnect electromigration test structures under stress.

• Designed four chip set to evaluate reliability and defect clustering for 2-micrometer CMOS p-well Wafer Scale Integration process.

• Fabricated set of JPL test chips (including Total Ionizing Dose Chip, Fault Chip and Reliability Chip) alongside JPL designed Direct Memory Access Coprocessor chip. These chips are to provide support for flight qualification of the DMAC.

• Received "Best Paper" award at 1989 International Conference on Microelectronic Test Structures. Presented timing sampler results, characterizing signal propagation delay.
Application Specific Integrated Circuits

Publications

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J. Lee, W. Fang, R. Rice
SPIE Proceedings, Los Angeles, CA, January, 1988

"A VLSI Design of a Pipeline Prime Factor DFT over Finite Design"
T. K. Truong, I. S. Hsu, H. C. Shyu, I. S. Reed, H. M. Shao

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T. K. Truong, I. S. Reed, L. J. Deutsch

"A VLSI Architecture for Performing Finite Field Arithmetic with Reduced Table Lookup"
I. S. Hsu, T. K. Truong, I. S. Reed, N. Glover

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I.S. Hsu, T.K. Truong
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I. Hsu
TDA Progress Report 42-96, Jet Propulsion Laboratory, Pasadena, CA, October - December, 1988

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M. Breuer
TDA Progress Report 42-96, Jet Propulsion Laboratory, Pasadena, CA, October - December, 1988

"Data Compression for on-board SAR Processor"
C. Chang, W. Fang, J. Curlander
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"A VLSI Design of Systolic Tree-Searched Vector Quantizer for Eos On-Board SAR Processor"
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D. Hendry
NASA Tech Brief NPO-17341 (patent pending)

"A VLSI Single Chip (255, 223) Reed-Solomon Encoder with Interleaver"
I.S. Hsu, T.K. Truong, L.J. Deutsch, I.S. Reed
NASA Tech Brief NPO-17280 (patent pending)

"A New VLSI Architecture for the Viterbi Decoder of Large Constraint Length Convolutional Codes"
I.S. Hsu, T.K. Truong, J. Sun, I.S. Reed
NASA Tech Brief NPO-17310 (patent pending)

"A Comparison of VLSI Architectures for Time and Transformation Domain Decoding of Reed-Solomon Codes"
I.S. Hsu, T.K. Truong, L.J. Deutsch, E. Satorius, I.S. Reed
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Quality Assurance and Space Qualification Methodology

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R.A. Allen, C.A. Pina, M.G. Buehler

"Comparison of Results from Simple Expressions for MOSFET Parameter Extraction"
M.G. Buehler, Y.-S. Lin

"CMOS Process Monitor"
M.G. Buehler, L.W. Linholm, V.C. Tyree, et. al.

"Comb/Serpentine/Cross-Bridge Test Structure for Fabrication Process Evaluation"
H.R. Sayah, M.G. Buehler

"Temperature Control in Wafer-Level Testing of Large Multi-Segment Electromigration Test Structures"
N. Zamani, Y.-S. Lin

"Fast and Accurate Wafer-Level Measurement of Temperature Profile in Multi-Segment Electromigration Test Structures"
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B.R. Blaes, M.G. Buehler, Y.-S. Lin, K.A. Hicks

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U. Lieneweg, D.J. Hannaman

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B.R. Blaes, M.G. Buehler
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"Chip-Level Electromigration Measurement Technique for Multi-Segmented Interconnect Test Structures"
N. Zamani, J. Dhiman, M.G. Buehler

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M.G. Buehler, B.R. Blaes, Y.-S. Lin
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"A Direct Method for Measuring the Gate Oxide Capacitances of MOSFETs"
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M.G. Buehler, B.R. Blaes, H.R. Sayah, U. Lienerweg
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M.G. Buehler, D.J. Hannaman
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B.R. Blaes, M.G. Buehler
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U. Lieneweg, D.J. Hannaman
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NASA Tech Brief NPO-17393

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B. R. Blaes, M. G. Buehler
NASA Tech Brief NPO-16645, U. S. Patent No. 4,688,947

"Measuring Critical Charges for Single Event Upset Phenomena"
B. R. Blaes, M. G. Buehler
NASA Tech Brief NPO-17073

"System Measures Logic-Gate Delays"
B. R. Blaes
NASA Tech Brief NPO-16646
Algorithms Tailored for ASIC Designs

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"Real-Time Data Compression for Eos-class Missions"
J. Lee, W. Fang, R. Rice
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"A Simplified Procedure for Correcting Both Errors and Erasures of Reed-Solomon Code"
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C.Y. Chang, J. Bowers, W. Fang
JPL Publication, D-6459 (JPL internal document), Jet Propulsion Laboratory, Pasadena, CA, June, 1989

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J. Sun, T.K. Truong, I.S. Reed, H.E. Huey
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A. Shiozaki, T.K. Truong, K.M. Cheung, I.S. Reed
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X.W. Yin, T.K. Truong, I.S. Reed, J.K. Holmes
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O. Collins, Follara, S. Dolinar, J. Statman
TDA Progress Report 42-96, Jet Propulsion Laboratory, Pasadena, CA

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CSMT-Caltech Campus Collaboration  
(Cumulative List)

T. Phillips  
D. Rutledge  
G. Fox  
P. Messina  
J. Hopfield  
C. Koch  
D. Psaltis  
J. D. Baldeschweiler  
F. Culick  
K. Vahala  
D. Goodstein  
R. Housely  
M. Cross  
D. Dougherty  
A. Yariv  
H. Gray  
A. Zewail  
R. Grubbs  
N. Yeh  
J. Pine  
L. Hood

Submillimeter Detectors  
Submillimeter Antennas  
Hypercube Concurrent Computing  
Hypercube Concurrent Computing  
Neural Networks, Molecular Computation  
Neural Networks  
Optical Processing  
Scanning Tunneling Microscopy  
Robotic Computing  
E-Beam Lithography  
High Tc Superconductivity  
High Tc Superconductivity  
High Tc Superconductivity  
Optical Switching Materials  
Infrared Detectors  
Molecular Electronics  
Optical Characterization  
Nonlinear Optical Materials  
High Tc Superconductivity  
Micromachined Silicon Biological Probes  
Custom VLSI for Genome Sequencing
Distinguished Visiting Scientists
(Cumulative List)

- Professor Albert W. Overhauser, Department of Physics, Purdue University
  - Chaired Professor
  - Member NAS
  - Buckley Prize Winner (1975)

- Professor Hadis Morkoc, Department of Electrical Engineering and Material Research Laboratory, University of Illinois
  - MBE semiconductor devices

- Dr. Robert Jaklevic, Principal Research Scientist, Ford Motor Co., Research Staff
  - Inventor of Superconducting Quantum Interference Devices (SQUID)
  - Inventor of Inelastic Electron Tunneling Spectroscopy

- Dr. C. Thomas Elliot, Royal Signals and Radar Establishment, United Kingdom
  - Leading international expert on IR technology
  - Inventor of the Sprite (Signal Processing in Element) detector

- Professor Lester Eastman, Electrical Engineering, Cornell University
  - Fellow of the IEEE
  - Member of the U.S. Government Advisory Committee on Electron Devices
  - Member National Academy of Engineering

- Professor Max Schultz, Department of Applied Physics, University of Erlangen, West Germany
  - Infrared imaging
  - Semiconductor interface characterization and silicon MBE
  - MOS physics

- Professor John Wilkins, Department of Physics, Cornell University
  - Solid state theory of metals, superconductors and semiconductors

- Professor O. Engstrom, Department of Solid State Electronics, Chalmers University of Technology, Gothenburg, Sweden
  - Energy properties of solid memory cells
• Professor Pieter Balk, Delft Institute of Technology, Delft, The Netherlands
  - Director of the Delft Institute of Microelectronics and Submicron Technology
  - MBE of III-V materials and SiGe
  - MOS physics

• Professor Floyd Humphrey, Department of Electrical Engineering, Boston University, Massachusetts
  - Magnetic mass random access memory
  - Microsecond optical studies of magnetic switching
  - 1988 IEEE Magnetics Society Achievement Award

• Professor C.D.W. Wilkinson, Department of Electronics and Electrical Engineering, University of Glasgow, United Kingdom
  - Nanometer electron beam lithography

• Dr. T. Andersson, Department of Physics, Chalmers University, Sweden
  - MBE of III-V materials
  - Interface formation in thin films

• Professor N. Farhat, Department of Electrical Engineering, University of Pennsylvania
  - Optical neural networks
  - Photonics

• Professor James Mayer, Department of Materials Science and Engineering, Cornell University
  - Francis Norwood Bard Professor of Materials Science and Engineering
  - RBS/channeling and ion beam modification of materials
  - Interdiffusion and reactions in thin films

• Professor L. Eric Cross, Department of Electrical Engineering, Pennsylvania State University
  - Former Director of Materials Research Laboratory
  - Ferroelectric thin films polysaccharides

• Dr. John Lambe, Ford Motor Co. (retired)
  - Superconductivity
  - Neural networks

• Professor James Rosenberg, Department of Electrical Engineering, Brown University
  - Germanium IR detectors
  - High speed devices
• Dr. L. Craig Davis, Ford Motor Co.
  - Theory of ballistic electron devices
  - Electronic structure devices of semiconductors

• Professor Eric Fossum, Department of Electrical Engineering, Columbia University
  - Charge-coupled device design and physics
  - MOS physics

• Professor Leo Schowalter, Department of Physics, Rensselaer Polytechnic Institute
  - Silicon molecular beam epitaxy
  - Ballistic electron emission microscopy

• Professor James Lukens, Department of Physics, State University of New York, Stony Brook
  - Superconducting terahertz local oscillator
Conferences and Workshops
(Sponsored and/or Hosted by CSMT)

- Polymers in Non-linear Integrated Optics (July 24, 1986)
- Neural Network Devices and Applications (February 18-19, 1987)
- Submillimeter (Terahertz) Receiver Technology (April 7-8, 1987)
- CLEO (April 27-May 1, 1987)
- Highly Parallel Fault-Tolerant Computers for Space Applications (June 9-10, 1987)
- International Conference on Scanning Tunneling Microscopy '87 (July 20-24, 1987)
- Congress of the International Commission for Optics (August 24-28, 1987)
- Neural Information Processing Systems - Real and Synthetic (November 8-12, 1987)
- Hypercube Concurrent Computers and Applications (January 19-21, 1988)
- Spatial Light Modulator and Applications (June, 1988)
- Microspacecraft for Space Science (July 6-7, 1988)
- Solid-State Terahertz Sources Workshop (August, 1988)
- American Vacuum Society, Southern California Section (January 1989)
- Hypercube Concurrent Computers and Applications (March, 1989)
- 1989 Space Cryogenics Workshop (July 1989)
- Technology Information Meeting - Microelectronics (November 1989)
The 1988-1989 Technical Report of the Jet Propulsion Laboratory Center for Space Microelectronics Technology summarizes the technical accomplishments, publications, presentations, and patents of the center during the past two years. The report lists 321 publications, 282 presentations, and 140 new technology reports and patents.